

PIC18(L)F25/26K83 Memory Programming Specification

1.0 OVERVIEW

This programming specification describes an SPI-based programming method for the PIC18(L)F25/26K83 family of microcontrollers. [Section 3.0 “Programming Algorithms”](#) describes the programming commands, programming algorithms and electrical specifications which are used in that particular programming method. [Appendix B](#) contains individual part numbers, device identification and checksum values, pinout and packaging information, and Configuration Words.

Note 1: This is a SPI-compatible programming method with 8-bit commands.

2: The low-voltage entry code is 32 clocks and MSb first.

1.1 Programming Data Flow

Nonvolatile Memory (NVM) programming data can be supplied by either the high-voltage In-Circuit Serial Programming™ (ICSP™) interface or the low-voltage In-Circuit Serial Programming (ICSP) interface. Data can be programmed into the Program Flash Memory (PFM), Data EEPROM Memory, dedicated “User ID” locations and the Configuration Words.

1.2 Write and/or Erase Selection

Erasing or writing is selected according to the command used to begin operation (see [Table 3-1](#)). The terminologies used in this document, related to erasing/writing to the Program Flash Memory, are defined in [Table 1-1](#) and are detailed below.

TABLE 1-1: PROGRAMMING TERMS

Term	Definition
Programmed Cell	A memory cell at logic ‘0’
Erased Cell	A memory cell at logic ‘1’
Erase	Change memory cell from a ‘0’ to a ‘1’
Write	Change memory cell from a ‘1’ to a ‘0’
Program	Generic erase and/or write

1.2.1 ERASING MEMORY

Program Flash Memory is erased by row or in bulk, where ‘bulk’ includes many subsets of the total memory space. Here, row refers to the minimum erasable size, and bulk is one of many possible subsets of all memory rows. The duration of the erase is determined by the size of program memory. All Bulk ICSP Erase commands have minimum V_{DD} requirements, which are higher than the Row Erase and write requirements. Refer to [Section 3.6 “Electrical Specifications”](#).

1.2.2 WRITING MEMORY

Program Flash Memory is written one row at a time. Multiple load data for NVM commands is used to fill the row data latches. The duration of the write can be determined either internally or externally. Refer to [Section 3.6 “Electrical Specifications”](#).

1.2.3 MULTI-WORD PROGRAMMING INTERFACE

Program Flash Memory (PFM) panels include a 64-word (one row) programming interface. Refer to [Table C-1](#) for row size of erase and write operations for the PIC18(L)F25/26K83 family. The row to be programmed must first be erased, either with a Bulk Erase or a Row Erase.

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1.3 Hardware Requirements

1.3.1 HIGH-VOLTAGE ICSP PROGRAMMING

In High-Voltage ICSP mode, the device requires two programmable power supplies: one for VDD and one for the MCLR/VPP pin.

1.3.2 LOW-VOLTAGE ICSP PROGRAMMING

In Low-Voltage ICSP mode, the device can be programmed using a single VDD source in the operating range. The MCLR/VPP pin does not have to be brought to programming voltage, but can instead be left at the normal operating voltage.

1.3.2.1 Single-Supply ICSP Programming

The device's LVP Configuration bit enables single-supply (low-voltage) ICSP programming. The LVP bit defaults to a '1' (enabled). The LVP bit may only be programmed to '0' by entering the High-Voltage ICSP mode, where the MCLR/VPP pin is raised to VIH. Once the LVP bit is programmed to a '0', only the High-Voltage ICSP mode is available and only the High-Voltage ICSP mode can be used to program the device.

Note 1: The High-Voltage ICSP mode is always available, regardless of the state of the LVP bit, by applying VIH to the MCLR/VPP pin.

2: While in Low-Voltage ICSP mode, MCLR is always enabled, regardless of the MCLRE bit. Also, the port pin can no longer be used as a general purpose input.

1.4 Pin Utilization

Five pins are needed for ICSP programming. The pins are listed in Table 1-2. Refer to Table B-3 for pin locations and packaging information.

TABLE 1-2: PIN DESCRIPTIONS DURING PROGRAMMING

Pin Name	During Programming		
	Function	Pin Type	Pin Description
ICSPCLK	ICSPCLK	I	Clock Input – Schmitt Trigger Input
ICSPDAT	ICSPDAT	I/O	Data Input/Output – Schmitt Trigger Input
MCLR/VPP	Program/Verify mode	I ⁽¹⁾	Program Mode Select
VDD	VDD	P	Power Supply
VSS	VSS	P	Ground

Legend: I = Input, O = Output, P = Power

Note 1: The programming high voltage is internally generated. To activate the Program/Verify mode, high voltage needs to be applied to the MCLR input. Since the MCLR is used for a level source, MCLR does not draw any significant current.

2.0 MEMORY MAP

TABLE 2-1: PROGRAM AND DATA EEPROM MEMORY MAP

PIC18(L)F25K83		PIC18(L)F26K83	
PC<21:0>		PC<21:0>	
Stack (31 levels)		Stack (31 levels)	
00 0000h	Reset Vector	00 0000h	Reset Vector
...
00 0008h	Interrupt Vector High ⁽²⁾	00 0008h	Interrupt Vector High ⁽²⁾
...
00 0018h	Interrupt Vector Low ⁽²⁾	00 0018h	Interrupt Vector Low ⁽²⁾
00 001Ah	Program Flash Memory (16 KW) ⁽³⁾	00 001Ah	Program Flash Memory (32 KW) ⁽³⁾
00 7FFFh		00 7FFFh	
00 8000h		00 8000h	
00 FFFFh		00 FFFFh	
01 0000h	Not present	01 0000h	Not present
1F FFFFh	User IDs (8 Words) ⁽⁴⁾	1F FFFFh	User IDs (8 Words) ⁽⁴⁾
20 0000h		20 0000h	
...		...	
20 000Fh		20 000Fh	
20 0010h	Reserved	20 0010h	Reserved
...		...	
2F FFFFh		2F FFFFh	
30 0000h		30 0000h	
...	Configuration Words (5 Words) ⁽⁴⁾	...	Configuration Words (5 Words) ⁽⁴⁾
30 0009h		30 0009h	
30 000Ah		30 000Ah	
...		...	
30 FFFFh	Reserved	30 FFFFh	Reserved
31 0000h		31 0000h	
...		...	
31 00FFh		31 00FFh	
31 0400h	Reserved	31 0400h	Reserved
...		...	
3E FFFFh		3E FFFFh	
3F 0000h	Device Information Area ^{(4),(6)}	3F 0000h	Device Information Area ^{(4),(6)}
...		...	
3F 003Fh		3F 003Fh	
3F0040h		3F0040h	
...	Reserved	...	Reserved
3F FFFFh		3F FFFFh	
3F FF00h		3F FF00h	
...	Device Configuration Information (5 Words) ^{(4),(5),(6)}	...	Device Configuration Information (5 Words) ^{(4),(5),(6)}
3F FF09h		3F FF09h	
3F FF0Ah		3F FF0Ah	
...		...	
3F FFFBh	Reserved	3F FFFBh	Reserved
3F FFFCh		3F FFFCh	
...		...	
3F FFFDh		3F FFFDh	
3F FFFEh	Revision ID (1 Word) ^{(4),(5),(6)}	3F FFFEh	Revision ID (1 Word) ^{(4),(5),(6)}
...		...	
3F FFFFh	Device ID (1 Word) ^{(4),(5),(6)}	3F FFFFh	Device ID (1 Word) ^{(4),(5),(6)}
...		...	

- Note**
- 1: The stack is a separate SRAM panel, apart from all user memory panels.
 - 2: 00 0008h location is used as the reset default for IVTBASE register, the vector table can be relocated in the memory by programming IVTBASE register.
 - 3: Storage Area Flash is implemented as the last 128 Words of User Flash, if present.
 - 4: Not code-protected.
 - 5: Device Configuration Information, Device/Revision IDs are hard-coded in silicon.
 - 6: This region cannot be written by the user and it is not affected by a bulk erase.

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2.1 User ID Location

A user may store identification information (User ID) in eight designated locations. The User ID locations are mapped to 20 0000h-20 000Fh. Code protection has no effect on these memory locations. Each location may be read with code protection enabled or disabled.

2.2 Device Information Area

The Device Information Area (DIA) is a dedicated region in the Program Flash Memory. The data is mapped from 3F 0000h to 3F 003Fh. These locations are read-only and cannot be erased or modified. The DIA holds the calibration data for the temperature indicator module and the ADC FVR values which are useful for temperature sensing applications and calibration. For more information, refer to the *PIC18(L)F25/26K83 Data Sheet* (Future Release).

2.3 Device Configuration Information

The Device Configuration Information (DCI) is a dedicated region in the Program Flash Memory mapped from 3F FF00h to 3F FF09h. The data stored in the DCI memory is hard-coded into the device during manufacturing. Refer to [Table C-1](#) in [Appendix C: “Device Configuration Information”](#) for the complete DCI table address and description. The DCI holds information about the device which is useful for programming and bootloaders. These locations are read-only and cannot be erased or modified. For more information, refer to the *PIC18(L)F25/26K83 Data Sheet* (Future Release). These locations are read-only and cannot be erased or modified.

2.4 Device/Revision ID

The 16-bit Device ID Word is located at 3F FFFEh and the 16-bit Revision ID is located at 3F FFFCh. These locations are read-only and cannot be erased or modified. Refer to [Table B-1](#) for Device ID's.

REGISTER 2-1: DEVICEID: DEVICE ID REGISTER

R	R	R	R	R	R	R	R
DEV15	DEV14	DEV13	DEV12	DEV11	DEV10	DEV9	DEV8
bit 15							bit 8

R	R	R	R	R	R	R	R
DEV7	DEV6	DEV5	DEV4	DEV3	DEV2	DEV1	DEV0
bit 7							bit 0

Legend:

R = Readable bit '1' = Bit is set '0' = Bit is cleared x = Bit is unknown

bit 15-0 **DEV<15:0>**: Device ID bits⁽¹⁾

Note 1: Refer to [Table B-1](#) for Device ID Information.

REGISTER 2-2: REVISIONID: REVISION ID REGISTER

R	R	R	R	R	R	R	R
1	0	1	0	MJRREV<5:2>			
bit 15							bit 8

R	R	R	R	R	R	R	R
MJRREV<1:0>		MNRREV<5:0>					
bit 7							bit 0

Legend:

R = Readable bit '1' = Bit is set '0' = Bit is cleared x = Bit is unknown

bit 15-12 **Read as '1010'**

These bits are fixed with value, '1010', for all devices in this programming specification.

bit 11-6 **MJRREV<5:0>**: Major Revision ID bits

These bits are used to identify a major revision. A major revision is indicated by an all layer revision (A0, B0, C0, etc...).

Revision A = 6'b00_0000

bit 5-0 **MNRREV<5:0>**: Minor Revision ID bits

These bits are used to identify a minor revision.

Revision A0 = 6'b00_0000

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2.5 Configuration Words

The devices have five Configuration Words starting at address, 30 0000h. The individual bits within these Configuration Words are critical to the correct operation of the system. Configuration bits enable or disable specific features, placing these controls outside the normal software process, and they establish configured values prior to the execution of any software.

In terms of programming, these important Configuration bits should be considered:

1. LVP: Low-Voltage Programming Enable bit

1 = ON – Low-Voltage Programming is enabled. $\overline{\text{MCLR}}/\text{VPP}$ pin function is $\overline{\text{MCLR}}$.
MCLRE Configuration bit is ignored.

0 = OFF – High Voltage on $\overline{\text{MCLR}}/\text{VPP}$ must be used for programming.

It is important to note that the LVP bit cannot be written (to '0') while operating from the LVP programming interface. The purpose of this rule is to prevent the user from dropping out of LVP mode while programming from LVP mode, or accidentally eliminating LVP mode from the configuration state. For more information, see [Section 3.1.2 “Low-Voltage Programming \(LVP\) Mode”](#).

2. MCLRE: Master Clear ($\overline{\text{MCLR}}$) Enable bit

- If LVP = 1

RE3 pin function is $\overline{\text{MCLR}}$

- If LVP = 0

1 = $\overline{\text{MCLR}}$ pin is $\overline{\text{MCLR}}$

0 = $\overline{\text{MCLR}}$ pin function is a port defined function

3. $\overline{\text{CP}}$: User Program Flash Memory and Data EEPROM Code Protection bit

1 = OFF – User Program Flash Memory and Data EEPROM code protection is disabled

0 = ON – User Program Flash Memory and Data EEPROM code protection is enabled

For more information on code protection, see [Section 3.3 “Code Protection”](#).

3.0 PROGRAMMING ALGORITHMS

3.1 Program/Verify Mode

In Program/Verify mode, the program memory and the configuration memory can be accessed and programmed in serial fashion. ICSPDAT and ICSPCLK are used for the data and the clock, respectively. All commands and data words are transmitted MSb first. Data changes on the rising edge of the ICSPCLK and is latched on the falling edge. In Program/Verify mode, both the ICSPDAT and ICSPCLK are Schmitt Trigger inputs. The sequence that enters the device into Program/Verify mode places all other logic into the Reset state. Upon entering Program/Verify mode, all I/Os are automatically configured as high-impedance inputs. On entering the Program/Verify mode, the address is cleared.

3.1.1 HIGH-VOLTAGE PROGRAM/VERIFY MODE ENTRY AND EXIT

There are two different modes of entering Program/Verify mode via high voltage:

- VPP – First Entry mode
- VDD – First Entry mode

3.1.1.1 VPP – First Entry Mode

To enter Program/Verify mode via the VPP-First mode, the following sequence must be followed:

1. Hold ICSPCLK and ICSPDAT low. All other pins should be unpowered.
2. Raise the voltage on $\overline{\text{MCLR}}$ from 0V to $V_{\text{IH}}H$.
3. Raise the voltage on VDD from 0V to the desired operating voltage.

The VPP-First entry prevents the device from executing code prior to entering Program/Verify mode. For example, when the Configuration Word has already been programmed to have $\overline{\text{MCLR}}$ disabled ($\text{MCLRE} = 0$), the Power-up Timer disabled ($\text{PWRTS}[1:0] = 11$) and the internal oscillator selected, the device will execute code immediately. Since this may prevent entry, VPP-First Entry mode is strongly recommended as it prevents user code from changing EEPROM contents or driving pins to affect Test mode entry. See the timing diagram in [Figure 3-1](#).

3.1.1.2 VDD – First Entry Mode

To enter Program/Verify mode via the VDD-First mode, the following sequence must be followed:

1. Hold ICSPCLK and ICSPDAT low.
2. Raise the voltage on VDD from 0V to the desired operating voltage.
3. Raise the voltage on $\overline{\text{MCLR}}$ from VDD or below to $V_{\text{IH}}H$.

The VDD-First mode is useful for programming the device when VDD is already applied, for it is not necessary to disconnect VDD to enter Program/Verify mode. During this cycle, any executing code will be interrupted and halted. See the timing diagram in [Figure 3-2](#).

3.1.1.3 Program/Verify Mode Exit

To exit Program/Verify mode, lower $\overline{\text{MCLR}}$ from $V_{\text{IH}}H$ to V_{IL} . VPP-First Entry mode should use VPP-Last Exit mode (see [Figure 3-1](#)). VDD-First Entry mode should use VDD-Last Exit mode (see [Figure 3-2](#)).

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FIGURE 3-1: PROGRAMMING ENTRY AND EXIT MODES – VPP-First AND Last

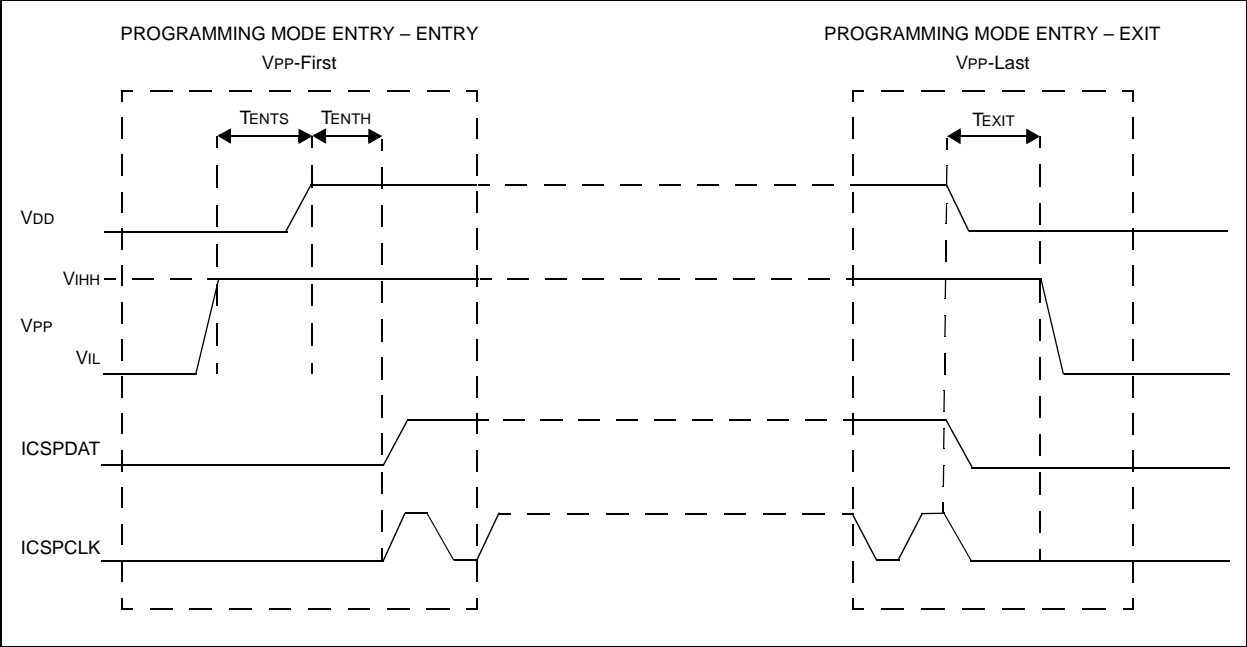
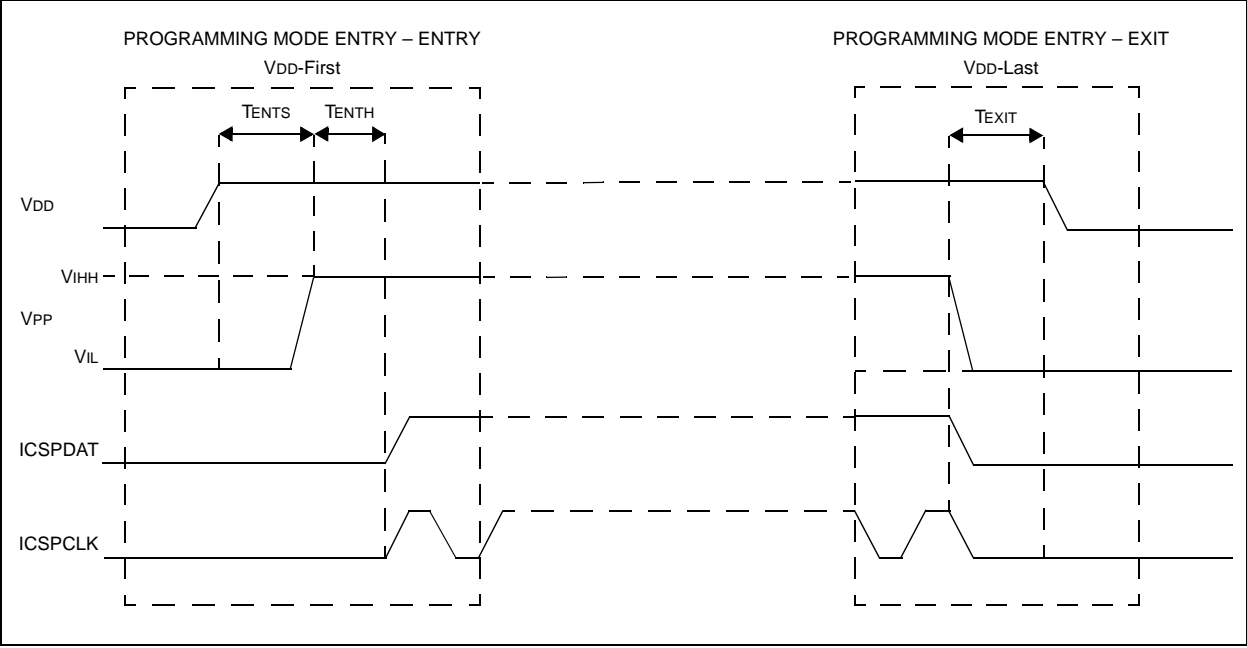


FIGURE 3-2: PROGRAMMING ENTRY AND EXIT MODES – VDD-First AND Last



3.1.2 LOW-VOLTAGE PROGRAMMING (LVP) MODE

The Low-Voltage Programming mode allows the devices to be programmed using VDD only, without high voltage. When the LVP bit of the Configuration Word 4H register is set to '1', the Low-Voltage ICSP Programming entry is enabled. To disable the Low-Voltage ICSP mode, the LVP bit must be programmed to '0'. This can only be done while in the High-Voltage Entry mode.

Entry into the Low-Voltage ICSP Program/Verify mode requires the following steps:

1. $\overline{\text{MCLR}}$ is brought to VIL.
2. A **32-bit key sequence** is presented on ICSPDAT. The LSb of the pattern is a "don't care x". The Program/Verify mode entry pattern detect hardware verifies only the first 31 bits of the sequence and the last clock is required before the pattern detect goes active.

The key sequence is a specific 32-bit pattern, '32'h4d434850' (more easily remembered as MCHP in ASCII). The device will enter Program/Verify mode only if the sequence is valid. The Most Significant bit of the Most Significant nibble must be shifted in first. Once the key sequence is complete, $\overline{\text{MCLR}}$ must be held at VIL for as long as Program/Verify mode is to be maintained. For Low-Voltage Programming timing, see [Figure 3-3](#) and [Figure 3-4](#).

FIGURE 3-3: LVP ENTRY (POWERING UP)

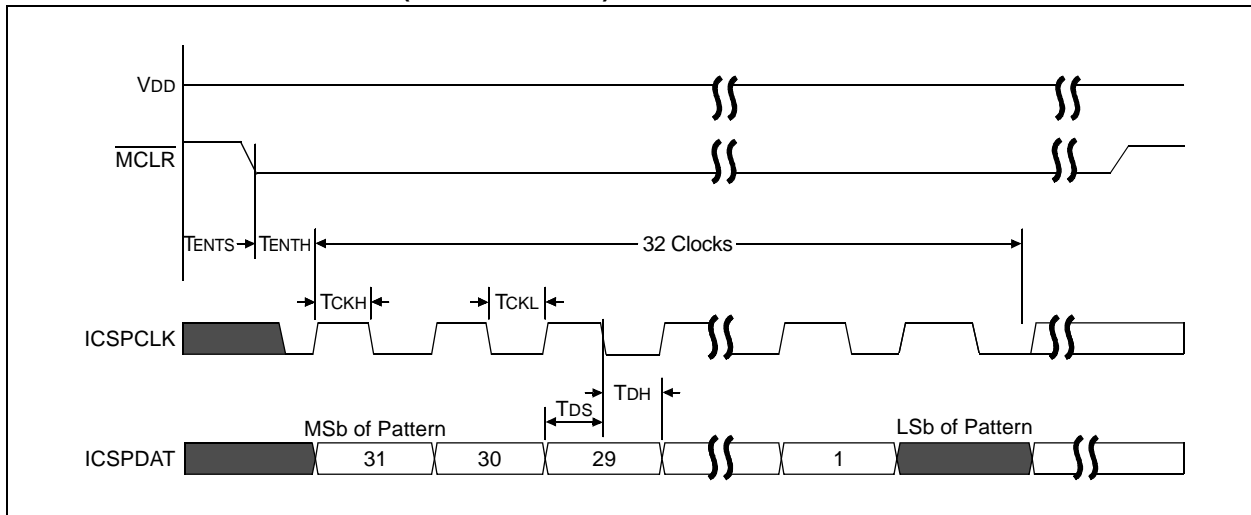
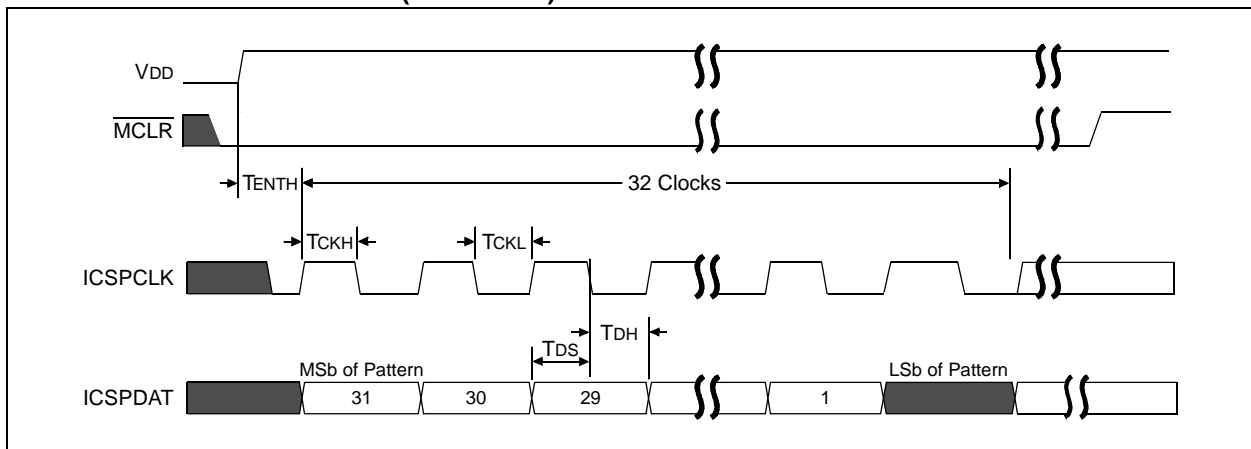


FIGURE 3-4: LVP ENTRY (POWERED)



Exiting Program/Verify mode is done by raising $\overline{\text{MCLR}}$ from below VIL to VIH level (or higher, up to VDD).

Note: To enter LVP mode, the MSb of the Most Significant nibble must be shifted in first. This differs from entering the key sequence on some other device families.

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3.1.3 PROGRAM/VERIFY COMMANDS

Once a device has entered ICSP Program/Verify mode (using either high-voltage or LVP entry), the programming host device may issue nine commands to the microcontroller, each eight bits in length. The commands are summarized in [Table 3-1](#). The commands are used to erase or program the device based on the location of the Program Counter (PC).

Some of the 8-bit commands also have a data payload associated with it (such as Load Data for NVM and Read Data from NVM).

If the programming host device issues an 8-bit command byte that has a data payload associated with it, the host device is responsible for sending an additional 24 clock pulses (for example, three 8-bit bytes) in order to send or receive the payload data associated with the command.

The payload field size is used so as to be compatible with many 8-bit SPI-based systems. Within each 24-bit payload field, the first bit transmitted is always a Start bit, followed by a variable number of Pad bits, followed by the useful data payload bits and ending with one Stop bit. The useful data payload bits are always transmitted Most Significant bit (MSb) first.

When the programming device issues a command that involves a host to microcontroller payload (for example, Load PC Address), the Start, Stop and Pad bits should all be driven by the programmer to '0'. When the programming host device issues a command that involves microcontroller to host payload data (for example, Read Data from NVM), the Start, Stop and Pad bits should be treated as "don't care" bits and the values should be ignored by the host.

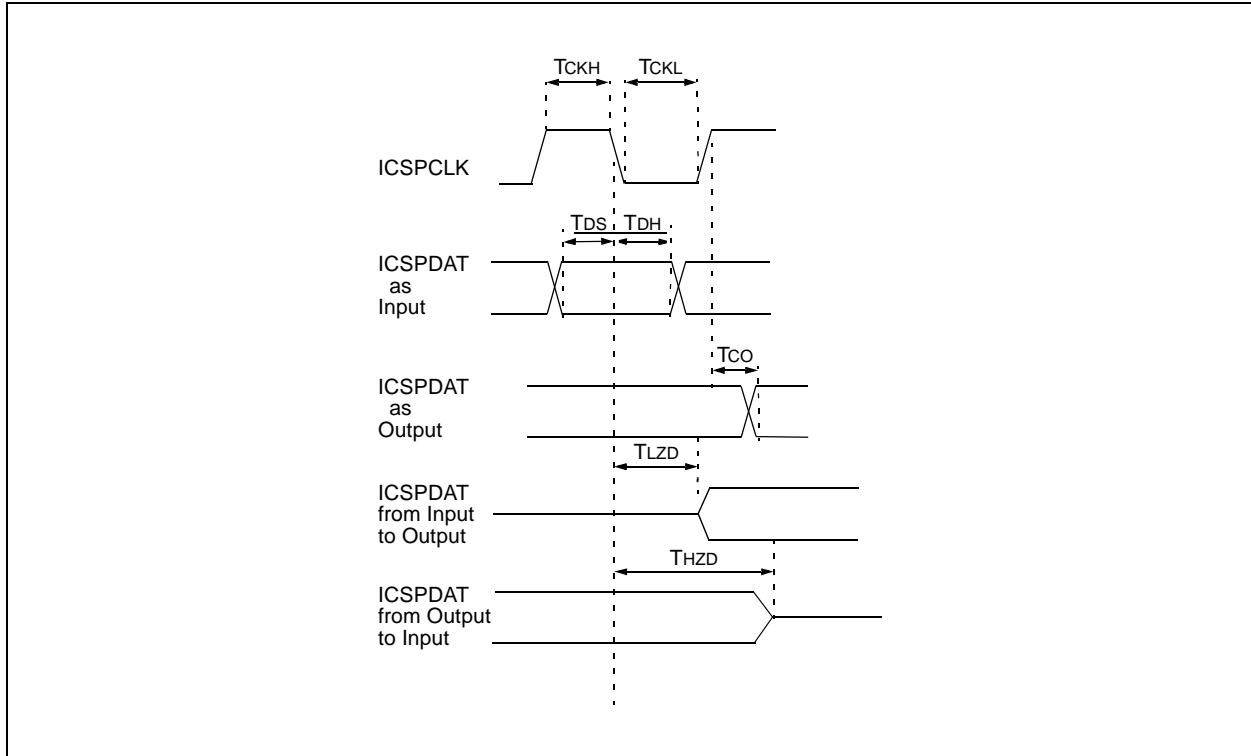
When the programming host device issues an 8-bit command byte to the microcontroller, the host should wait a minimum amount of delay (which is command-specific) prior to sending any additional clock pulses (associated with either a 24-bit data payload field or the next command byte).

TABLE 3-1: ICSP™ COMMAND SET SUMMARY

Command Name	Command Value		Payload Expected	Delay after Command	Data/Note
	Binary (MSb ... LSB)	Hex			
Load PC Address	1000 0000	80	Yes	TDLY	Payload value = PC
Bulk Erase Program Memory	0001 1000	18	No	TERAB	Depending on the current value of the PC, one or more memory regions.
Row Erase Program Memory	1111 0000	F0	No	TERAR	The row addressed by the MSBs of the PC is erased; LSBs are ignored.
Load Data for NVM	0000 00J0	00/02	Yes	TDLY	Data is loaded to the data latch addressed by the PC; J = 0: PC is unchanged J = 1: PC = PC + 2 after writing
Read Data from NVM	1111 11J0	FC/FE	Yes	TDLY	Data output '0' if code-protect is enabled; J = 0: PC is unchanged J = 1: PC = PC + 2 after reading
Increment Address	1111 1000	F8	No	TDLY	PC = PC + 2
Begin Internally Timed Programming	1110 0000	E0	No	TPINT	Commits latched data to NVM (self-timed).
Begin Externally Timed Programming	1100 0000	C0	No	TPEXT	Commits latched data to NVM (externally timed). After TPEXT, "End Externally Timed Programming" command must be issued.
End Externally Timed Programming	1000 0010	82	No	TDIS	Should be issued within required time delay (TPEXT) after "Begin Externally Timed Programming" command.

Note: All clock pulses for both the 8-bit commands and the 24-bit payload fields are generated by the host programming device. The microcontroller does not drive the ICSPCLK line. The ICSPDAT signal is a bidirectional data line. For all commands and payload fields, except the Read Data from NVM payload, the host programming device continuously drives the ICSPDAT line. Both the host programmer device and the microcontroller should latch received ICSPDAT values on the falling edge of the ICSPCLK line. When the microcontroller receives ICSPDAT line values from the host programmer, the ICSPDAT values must be valid a minimum of T_{DS} before the falling edges of ICSPCLK and should remain valid for a minimum of T_{DH} after the falling edge of ICSPCLK. See Figure 3-5.

FIGURE 3-5: CLOCK AND DATA TIMING



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3.1.3.1 Load Data for NVM

The Load Data for NVM command is used to load one programming data latch (for example, one 16-bit instruction word for program memory/configuration memory/User ID memory or one 8-bit data for a Data EEPROM Memory address). The latched data is written into program or EEPROM memory after the Begin Internally Timed Programming or Begin Externally Timed Programming command is issued (see [Section 3.2 “Programming Algorithms”](#)). The Load Data for the NVM command can be used to load data for Program Flash Memory (PFM) (see [Figure 3-6](#)) or the Data EEPROM Memory (see [Figure 3-7](#)). Depending on the value of bit 1 of the command, the PC may or may not be incremented (see [Table 3-1](#)).

FIGURE 3-6: LOAD DATA FOR NVM (PFM)

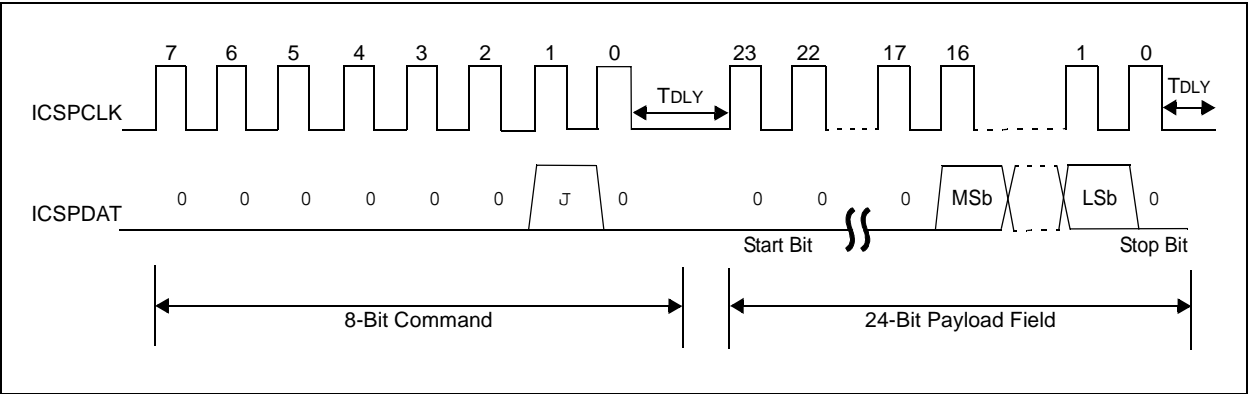
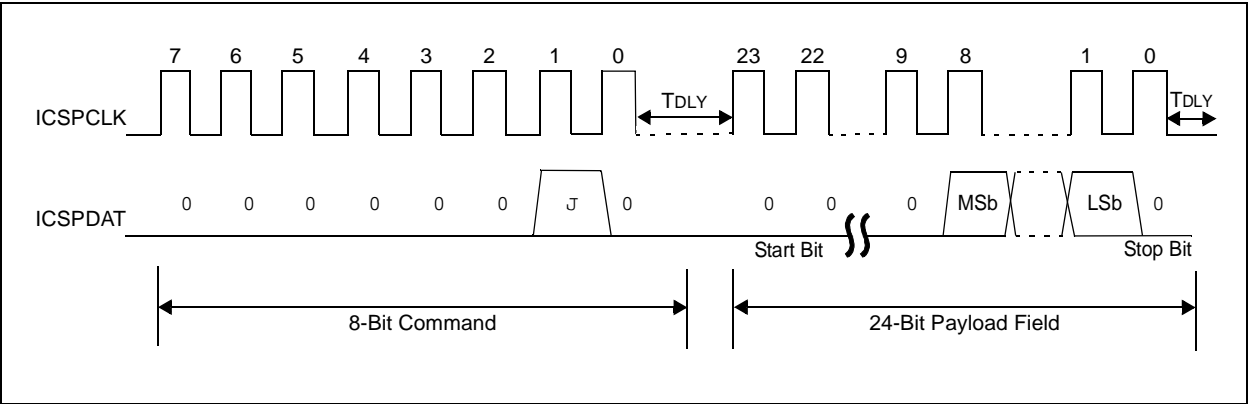


FIGURE 3-7: LOAD DATA FOR NVM (DATA EEPROM)



3.1.3.2 Read Data from NVM

The Read Data from NVM command will transmit data bits out of the current PC address. The ICSPDAT pin will go into Output mode on the first falling edge of the ICSP data payload clock and it will revert to Input mode (high-impedance) after the 24th falling edge of the ICSP data payload clock. The Start and Stop bits are only one-half-of-a-bit-time wide; therefore, they should be ignored by the host programmer device, since the latched value may be indeterminate. Additionally, the host programmer device should only consider the MSb to LSb payload bits as valid and should ignore the values of the Pad bits. If the program memory is code-protected ($\overline{CP} = 0$), the data will be read as zeros (see Figure 3-8 and Figure 3-9). Depending on the value of bit<1> of the command, the PC may or may not be incremented (see Table 3-1). The Read Data for NVM command can be used to read data for Program Flash Memory (PFM) (see Figure 3-8) or the Data EEPROM Memory (see Figure 3-9).

FIGURE 3-8: READ DATA FROM NVM (PFM OR CONFIGURATION WORDS)

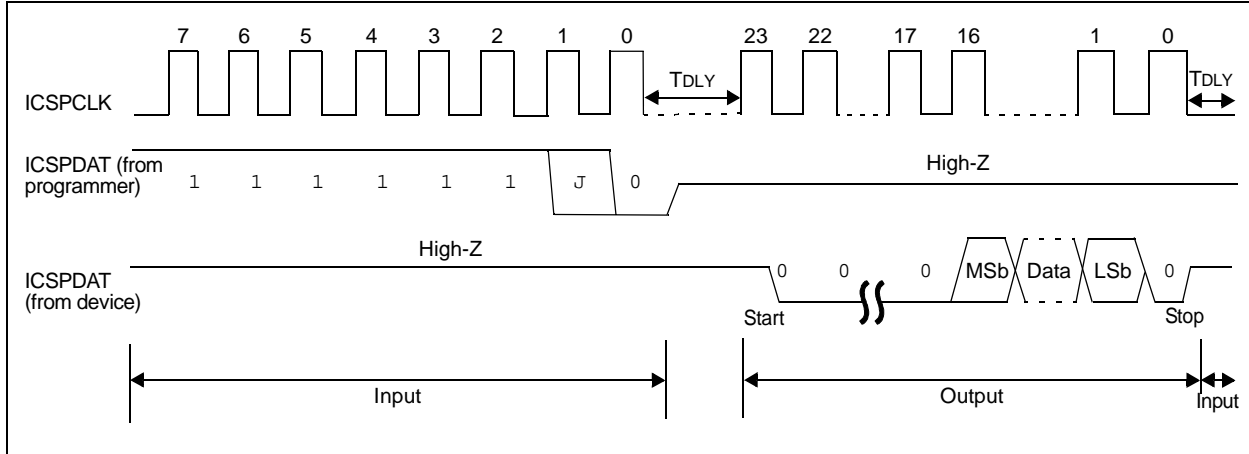
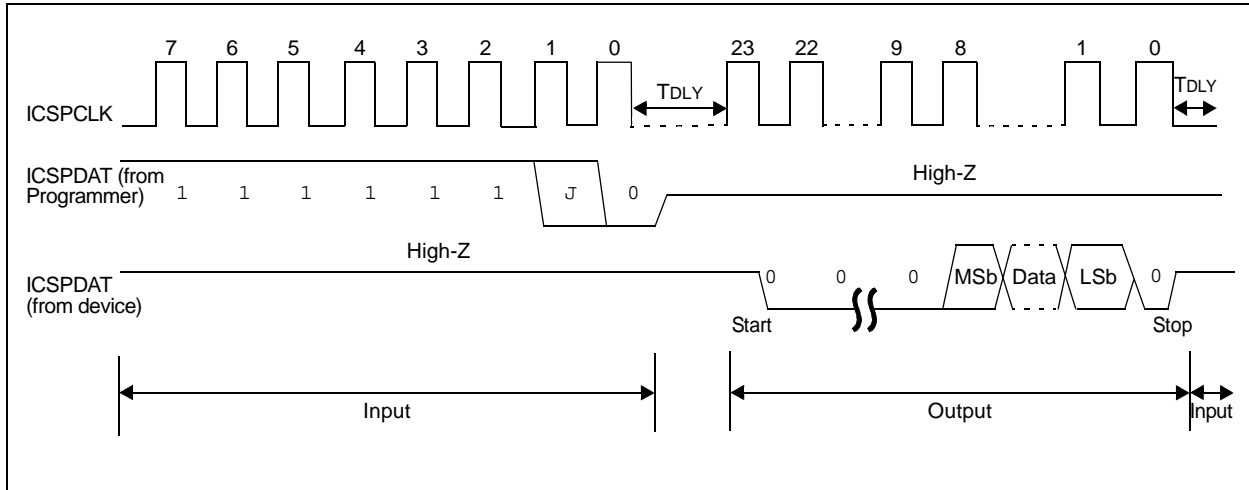


FIGURE 3-9: READ DATA FROM NVM (DATA EEPROM)

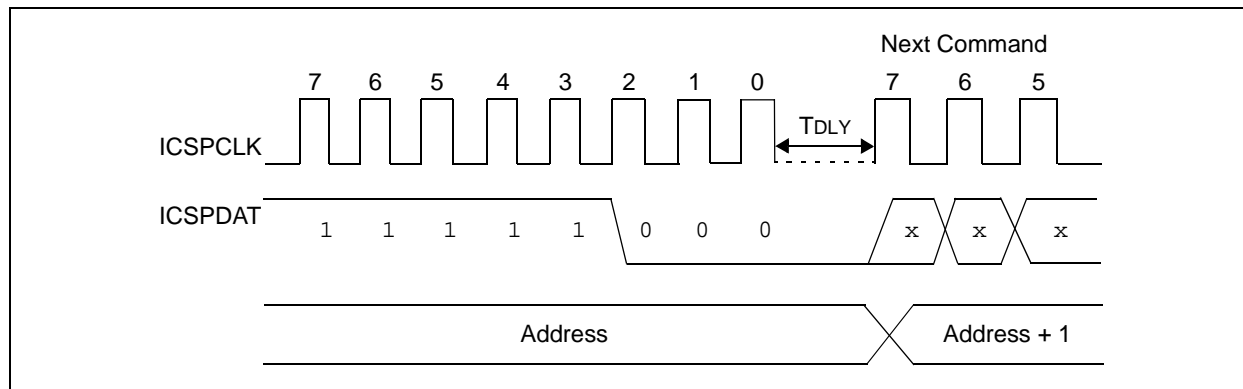


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3.1.3.3 Increment Address

The address is incremented when this command is received. Depending on the current value of the Program Counter, the increment varies. If the PC points to PFM, then the PC is incremented by 2; if the PC points to data EEPROM, then it is incremented by 1. It is not possible to decrement the address. To reset this counter, the user must use the Load PC Address command.

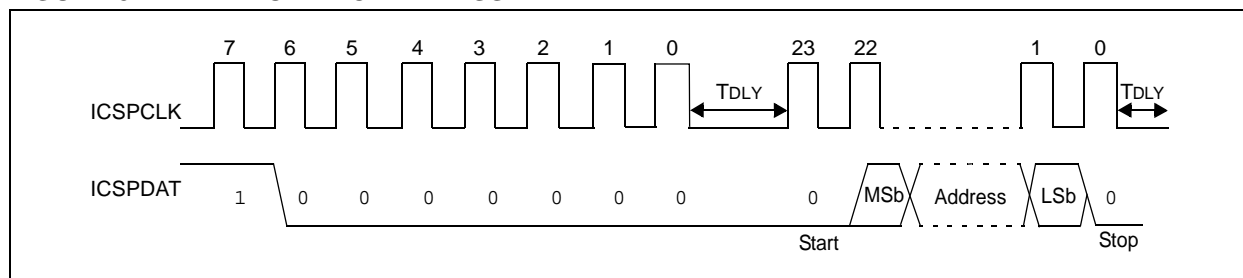
FIGURE 3-10: INCREMENT ADDRESS



3.1.3.4 Load PC Address

The PC value is set using the supplied data. The address implies the memory panel (PFM or Data EEPROM Memory) to be accessed (see [Figure 3-11](#)).

FIGURE 3-11: LOAD PC ADDRESS

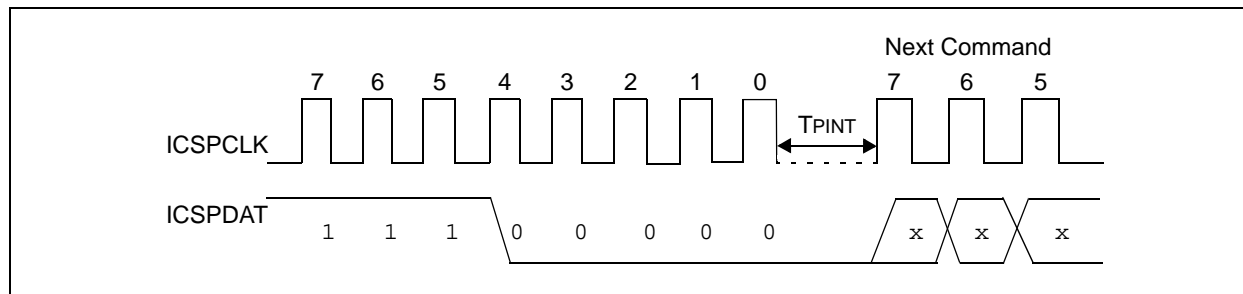


3.1.3.5 Begin Internally Timed Programming

The write programming latches must already have been loaded using the Write Data for NVM command, prior to issuing the Begin Programming command (see [Section 3.2 “Programming Algorithms”](#)). Programming of the addressed memory will begin after this command is received. An internal timing mechanism executes the write. The user must allow for the erase/write cycle time, TP_{INT} , in order for the programming to complete, prior to issuing the next command byte (see [Figure 3-12](#)).

After the programming cycle is complete, all of the data latches are reset to '1'. The command is ignored when the fuse latched value of $\overline{CP} = 0$ (i.e., when Program Flash Memory or Data EEPROM memory is code protected).

FIGURE 3-12: BEGIN INTERNALLY TIMED PROGRAMMING

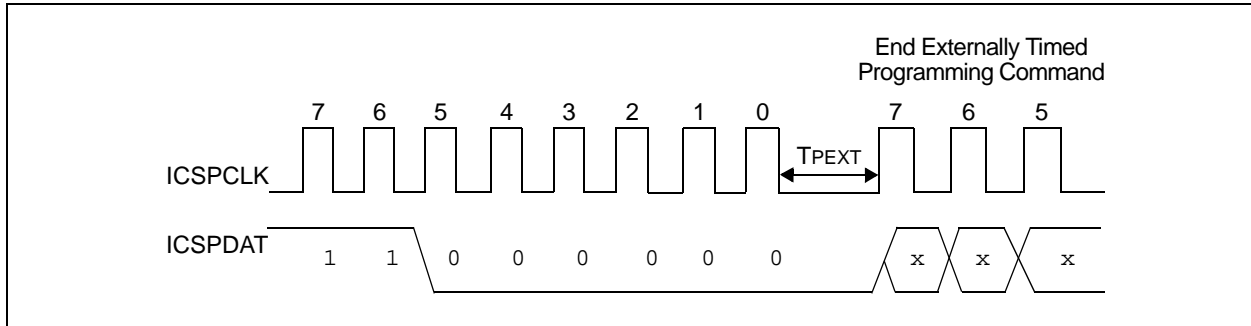


3.1.3.6 Begin Externally Timed Programming

Data to be programmed must be previously loaded by the Load Data for NVM command before every Begin Programming command. To complete the programming, the End Externally Timed Programming command must be sent in the specified time window defined by TPEXT (see Figure 3-13).

Externally timed writes are not supported for Configuration and Calibration bits. Any externally timed write to the Configuration or Calibration Word will have no effect on the targeted word.

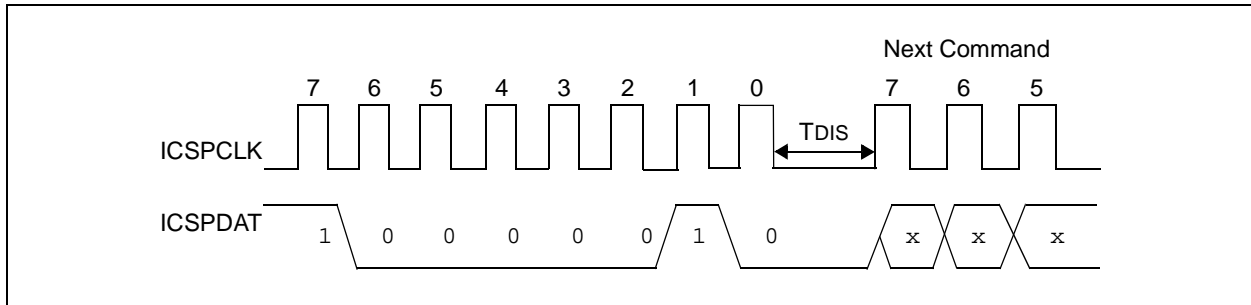
FIGURE 3-13: BEGIN EXTERNALLY TIMED PROGRAMMING



3.1.3.7 End Externally Timed Programming

This command is required to terminate the programming sequence after a Begin Externally Timed Programming command is given. If no programming command is in progress, or if the programming cycle is internally timed, this command will execute as a No Operation (NOP) (see Figure 3-14).

FIGURE 3-14: END EXTERNALLY TIMED PROGRAMMING



3.1.3.8 Bulk Erase Memory

The Bulk Erase command affects specific portions of the memory depending on the initial value of the Program Counter. Whenever a Bulk Erase command is executed, the device will erase all bytes within the regions listed in Table 3-2. An "End Programming" command is not required.

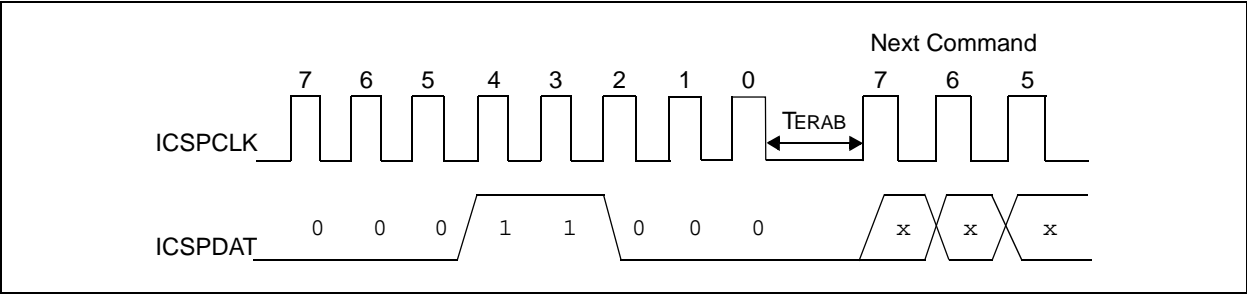
TABLE 3-2: BULK ERASE

Address	Area(s) Erased	
	$\overline{CP} = 1$ (code protection disabled)	$\overline{CP} = 0$ (code protection enabled)
00 0000h-01 FFFFh	Program Flash Memory Configuration Words	Program Flash Memory Data EEPROM Configuration Words
30 0000h-30 001Fh	Program Flash Memory User ID Words Configuration Words	Program Flash Memory Data EEPROM User ID Words Configuration Words
31 0000h-3E FFFFh	Data EEPROM	Data EEPROM

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After receiving the Bulk Erase Memory command, the erase will not complete until the time interval, TERAB, has expired (see [Figure 3-15](#)). The programming host device should not issue another 8-bit command until after the TERAB interval has fully elapsed.

FIGURE 3-15: BULK ERASE MEMORY



3.1.3.9 Row Erase Memory

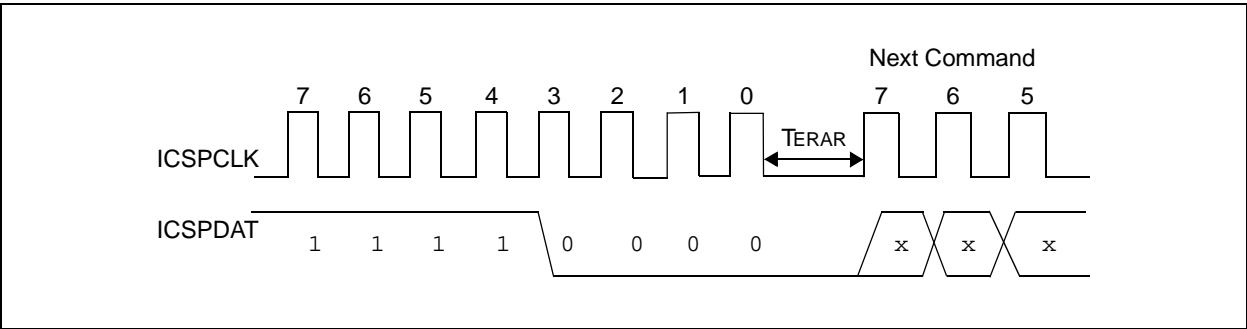
The Row Erase Memory command will erase an individual row based on the current address of the Program Counter. Write and erase operations are done on a row basis. Refer to [Table C-1](#) for row size of erase and write operations for PIC18(L)F25K83 and PIC18(L)F26K83 devices. For both PIC18(L)F25K83 and PIC18(L)F26K83 devices the row size (number of 16-bit words) for write/erase operation is 64, and the write latches per row (number of 8-bit latches) required for the write/erase operation is 128. If the program memory is code-protected, the Row Erase Program Memory command will be ignored.

The Flash memory row defined by the current PC will be erased. The user must wait TERAR for erasing to complete (see [Figure 3-16](#)).

TABLE 3-3: PROGRAM MEMORY ROW SIZES

Variant	Row Size (words)	Byte-Wide Write Latches per Row
PIC18(L)F25K83	64	128
PIC18(L)F26K83		

FIGURE 3-16: ROW ERASE MEMORY



3.2 Programming Algorithms

The devices use internal latches to temporarily store the 16-bit words used for programming. The data latches allow the user to write the program words with a single Begin Internally Timed Programming or Begin Externally Timed Programming command. The Load Data for NVM command is used to load a single data latch. The data latch will hold the data until the Begin Internally Timed Programming or Begin Externally Timed Programming command is given.

The data latches are aligned with the LSBs of the address. The address used at the time the Begin Internally Timed Programming or Begin Externally Timed Programming command is given will determine which memory row is written. Writes cannot cross a physical row boundary. For example, attempting to write from address, 0002h-0021h, in a 32-latch device will result in data being written to 0020h-003Fh.

If more than the maximum number of latches is written without a Begin Internally Timed Programming or Begin Externally Timed Programming command, the data in the data latches will be overwritten. [Figure 3-17](#) through [Figure 3-22](#) show the recommended flowcharts for programming.

Note: The Program Flash Memory regions are programmed one row at a time ([Figure 3-18](#)), while the User ID and Configuration Words are programmed one word at a time ([Figure 3-19](#)). The EEPROM memory is programmed one byte at a time. Refer to [Table C-1](#) for row size.

The value of the PC at the time of issuing the Begin Internally Timed Programming command determines what row (of Program Flash Memory or EEPROM) or what word (of User ID or Configuration Word) will get programmed.

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FIGURE 3-17: DEVICE PROGRAM/VERIFY FLOWCHART

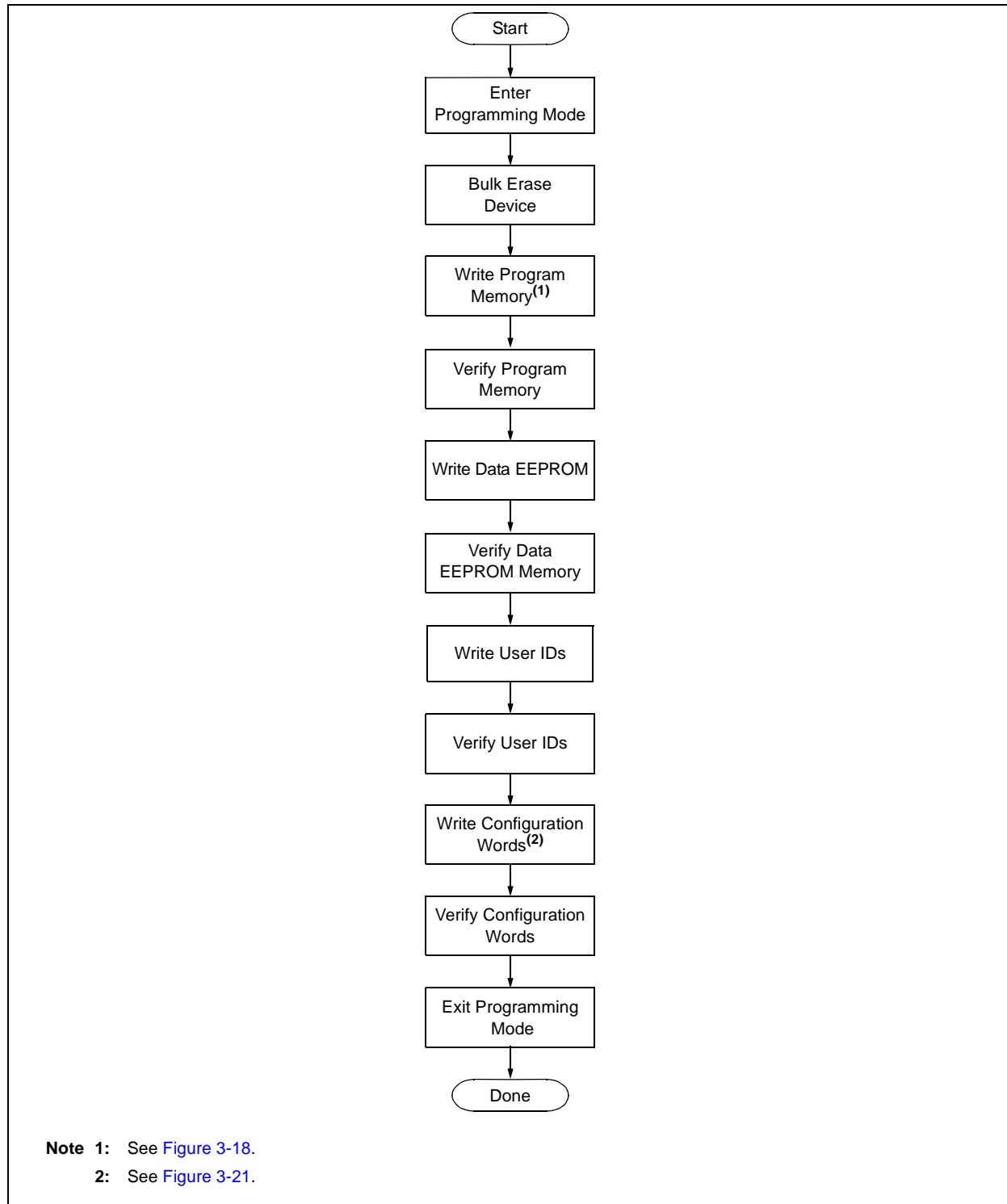


FIGURE 3-18: PROGRAM MEMORY FLOWCHART

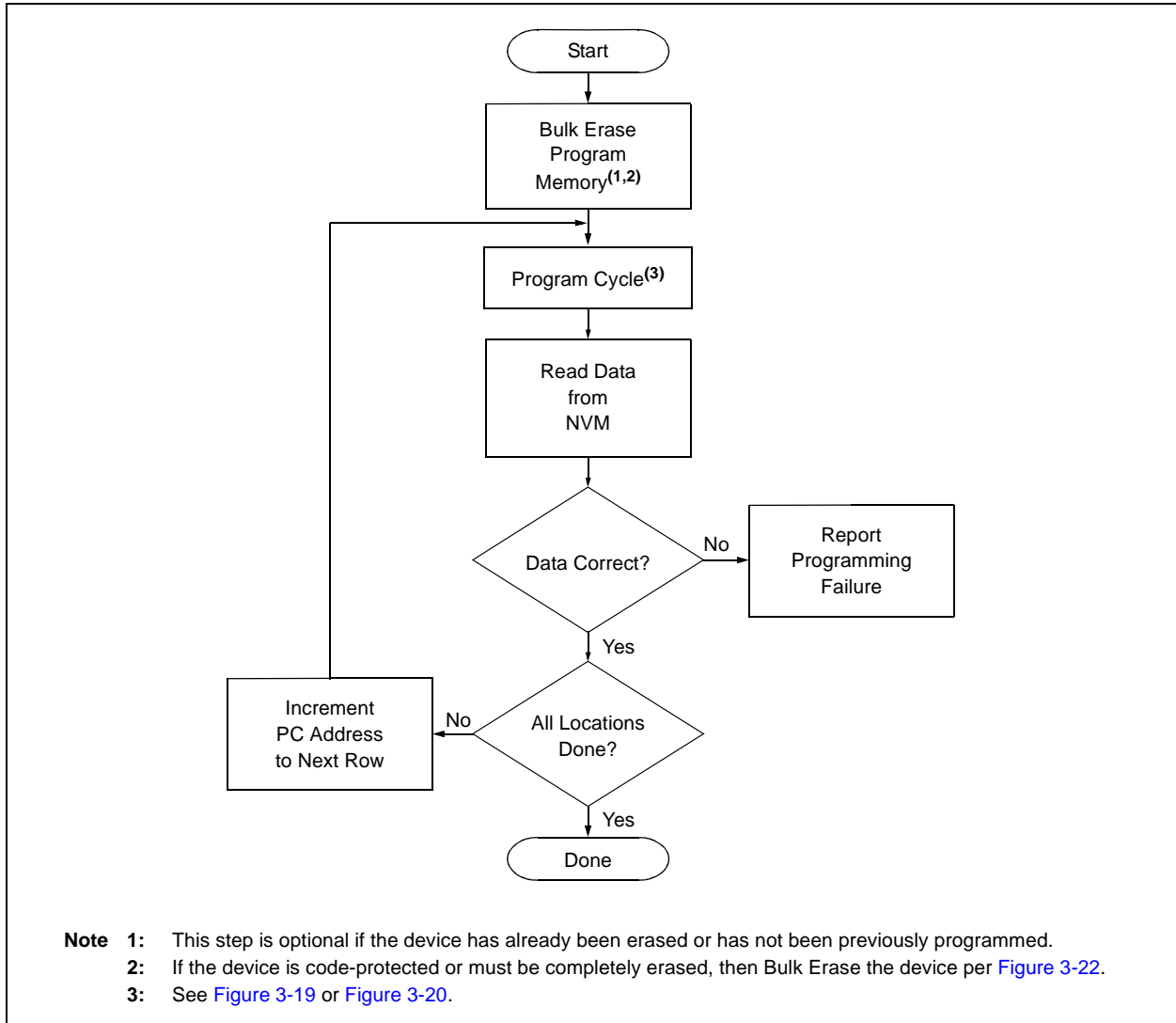


FIGURE 3-19: ONE-WORD PROGRAM CYCLE

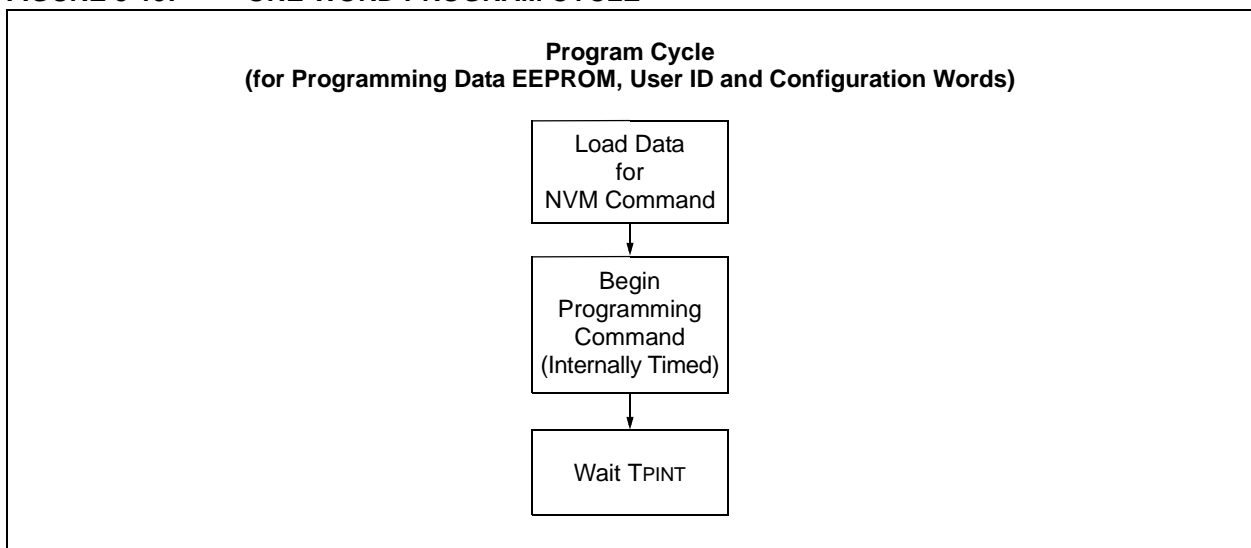


FIGURE 3-20: MULTIPLE WORD PROGRAM CYCLE

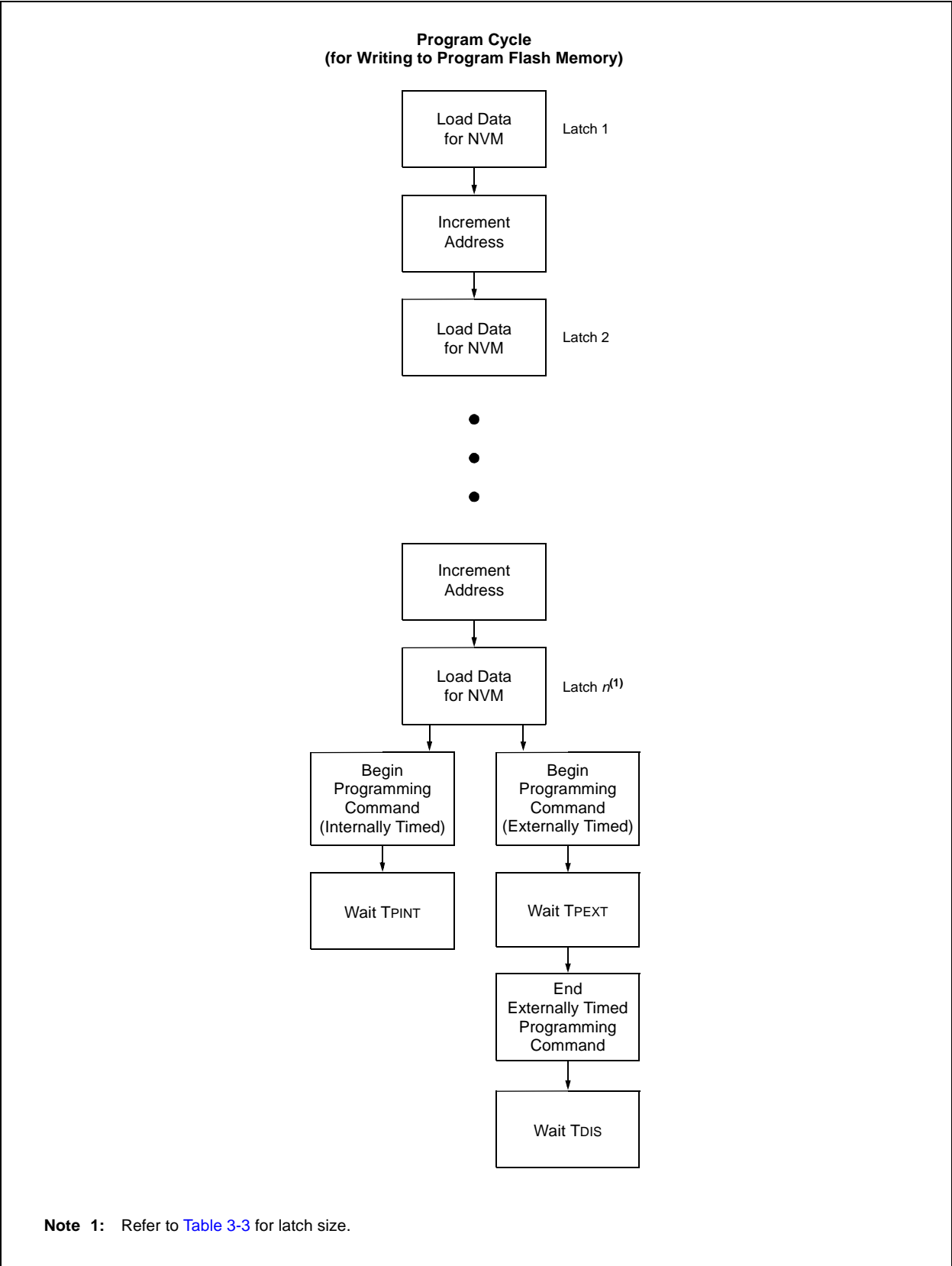
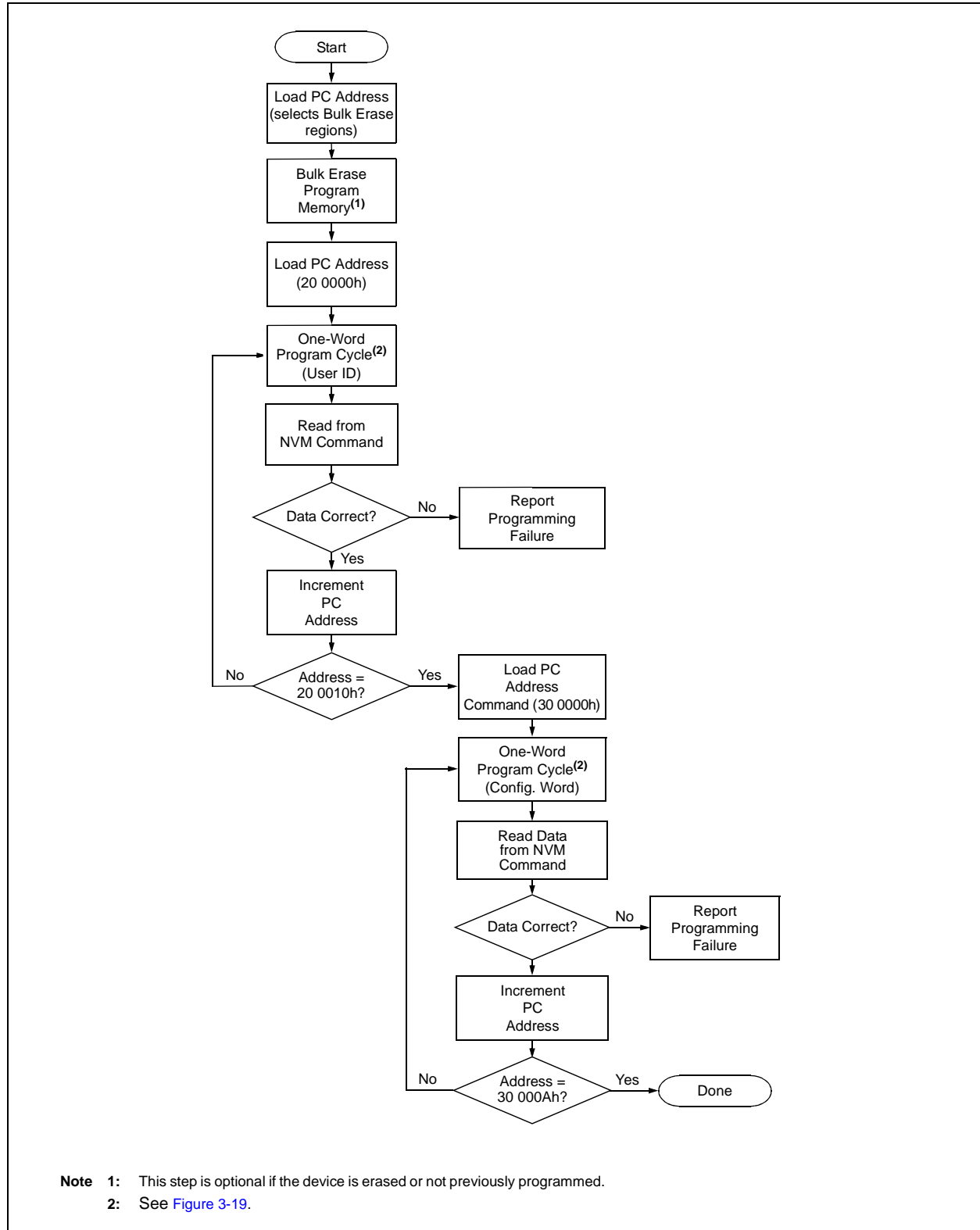
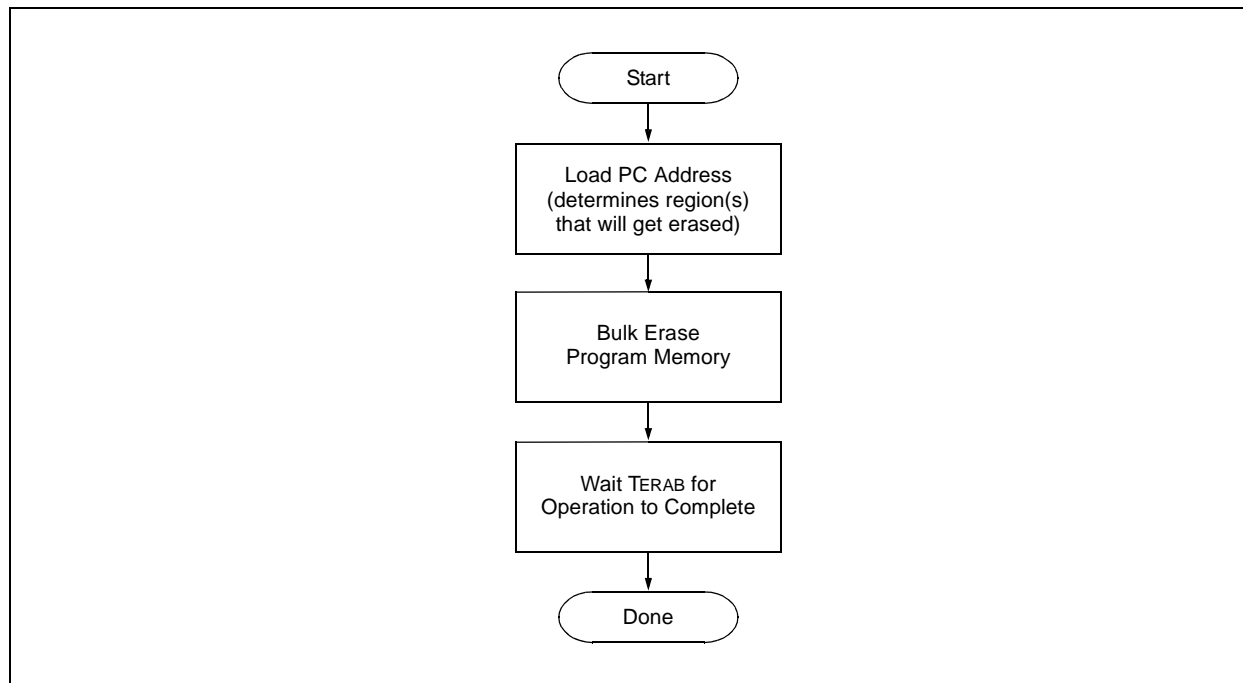


FIGURE 3-21: USER ID AND CONFIGURATION MEMORY PROGRAM FLOWCHART



PIC18(L)F25/26K83

FIGURE 3-22: BULK ERASE FLOWCHART



3.3 Code Protection

Code protection is controlled using the \overline{CP} bit. When code protection is enabled, all program memory and Data EEPROM locations read as '0'. Further programming is disabled for the program memory until the next Bulk Erase operation is performed. Program memory can still be programmed and read during program execution.

The Revision ID, Device ID, Device Information Area, User ID locations and Configuration Words can be read out regardless of the code protection settings.

3.4 Hex File Usage

3.4.1 EMBEDDING CONFIGURATION WORD INFORMATION IN THE HEX FILE

To allow portability of code, a programmer is required to read the Configuration Word locations from the Hex file. If Configuration Word information is not present in the Hex file, then a simple warning message should be issued. Similarly, while saving a Hex file, all Configuration Word information must be included. An option to not include the Configuration Word information may be provided. When embedding Configuration Word information in the Hex file, it should start at address, 300000h.

Microchip Technology Inc. feels strongly that this feature is important for the benefit of the end customer.

3.4.2 EMBEDDING DATA EEPROM INFORMATION IN THE HEX FILE

To allow portability of code, a programmer is required to read the data EEPROM information from the Hex file. If data EEPROM information is not present, a simple warning message should be issued. Similarly, when saving a Hex file, all data EEPROM information must be included. An option to not include the data EEPROM information may be provided. Microchip Technology Inc. consider this feature to be important for the benefit of the end customer.

3.5 Checksum Computation

The checksum is calculated by two different methods, dependent on the setting of the \overline{CP} Configuration bit. Refer to [Appendix B](#) for checksum computation examples.

3.5.1 PROGRAM CODE PROTECTION DISABLED

With the program code protection disabled, the checksum is computed by reading the contents of the program memory locations and adding up the program memory data, starting at address, 00 0000h, up to the maximum user-addressable location (e.g., 00 7FFFh for the PIC18F25K83 device). Any Carry bits exceeding 16 bits are ignored. Additionally, the relevant bits of the Configuration Words are added to the checksum. All unimplemented Configuration bits are masked to '0'.

3.5.2 PROGRAM CODE PROTECTION ENABLED

When the MPLAB® IDE check box for “Configure → ID Memory... → Use Unprotected Checksum” is checked, then the 16-bit checksum of the equivalent unprotected device is computed and stored in the User ID. The unprotected checksum is distributed one nibble per ID location. Each nibble is right justified.

The checksum of a code-protected device is computed in the following manner:

- All of the User ID locations are added to create the sum ID
- The sum ID is then added to the Configuration bits
- All unimplemented Configuration bits are masked to '0'

<p>Note: The checksum calculation differs depending on the code-protect setting. Since the code memory locations read out differently, depending on the code-protect setting, the examples in Appendix B describe how to manipulate the actual code memory values to simulate the values that would be read from a protected device. When calculating a checksum by reading a device, the entire code memory can simply be read and summed. The Configuration Word and ID locations can always be read.</p>
--

PIC18(L)F25/26K83

3.6 Electrical Specifications

Refer to the device-specific data sheet for absolute maximum ratings.

TABLE 3-4: AC/DC CHARACTERISTICS TIMING REQUIREMENTS FOR PROGRAM/VERIFY MODE

AC/DC CHARACTERISTICS			Standard Operating Conditions Production tested at +25°C				
Sym.	Characteristics		Min.	Typ.	Max.	Units	Conditions/Comments
Programming Supply Voltages and Currents							
VDD	Supply Voltage (VDDMIN, VDDMAX)	PICXXLFXXKXX	1.80	—	3.60	V	Note 1
		PICXXFXXKXX	2.30	—	5.50	V	
VPEW	Read/Write and Row Erase Operations		VDDMIN	—	VDDMAX	V	
VBE	Bulk Erase Operations		VBORMAX	—	VDDMAX	V	Note 2
IDDI	Current on VDD, Idle		—	—	1.0	mA	
IDDP	Current on VDD, Programming		—	—	5.0	mA	
IPP	VPP						
	Current on MCLR/VPP		—	—	600	μA	
VIHH	High Voltage on MCLR/VPP for Program/Verify Mode Entry		7.9	—	9.0	V	
TVHHR	MCLR Rise Time (VIL to VIHH) for Program/Verify Mode Entry		—	—	1.0	μs	
VIH	I/O Pins						
	(ICSPCLK, ICSPDAT, MCLR/VPP) Input High Level		0.8 VDD	—	VDD	V	
VIL	(ICSPCLK, ICSPDAT, MCLR/VPP) Input Low Level		VSS	—	0.2 VDD	V	
VOH	ICSPDAT Output High Level		VDD – 0.7 VDD – 0.7 VDD – 0.7	—	—	V	IOH = -3.5 mA, VDD = 5V IOH = -3 mA, VDD = 3.3V IOH = -1 mA, VDD = 1.8V
VOL	ICSPDAT Output Low Level		—	—	VSS + 0.6 VSS + 0.6 VSS + 0.6	V	IOL = 8 mA, VDD = 5V IOL = 6 mA, VDD = 3.3V IOL = 1.8 mA, VDD = 1.8V
Programming Mode Entry and Exit							
TENTS	Programing Mode Entry Setup Time: ICSPCLK, ICSPDAT Setup Time before VDD or MCLR↑		100	—	—	ns	
TENTH	Programing Mode Entry Hold Time: ICSPCLK, ICSPDAT Hold Time after VDD or MCLR↑		250	—	—	μs	
Serial Program/Verify							
TCKL	Clock Low Pulse Width		100	—	—	ns	
TCKH	Clock High Pulse Width		100	—	—	ns	
Tds	Data in Setup Time before Clock↓		100	—	—	ns	
TDH	Data in Hold Time after Clock↓		100	—	—	ns	
TCO	Clock↑ to Data Out Valid (during a Read Data command)		0	—	80	ns	

- Note 1:** Bulk Erased devices default to Brown-out Reset enabled with BORV = 1 (low trip point). VDDMIN is the VBOR threshold (with BORV = 1) when performing Low-Voltage Programming on a Bulk Erased device to ensure that the device is not held in Brown-out Reset.
- Note 2:** The hardware requires VDD to be above the BOR threshold, at the ~2.4V nominal setting, in order to perform Bulk Erase operations. This threshold does not depend on the BORV Configuration bit settings. The threshold is the same for both F and LF devices, even though the LF devices may not have a user-configurable ~2.4V nominal BOR trip point setting. Refer to the microcontroller device data sheet specifications for min./typ./max. limits of the VBOR level (at the BORV = 0 setting of F devices).
- Note 3:** Externally timed writes are not supported for Configuration and Calibration bits.

TABLE 3-4: AC/DC CHARACTERISTICS TIMING REQUIREMENTS FOR PROGRAM/VERIFY MODE (CONTINUED)

AC/DC CHARACTERISTICS		Standard Operating Conditions Production tested at +25°C				
Sym.	Characteristics	Min.	Typ.	Max.	Units	Conditions/Comments
TLZD	Clock↓ to Data Low-Impedance (during a Read Data command)	0	—	80	ns	
THZD	Clock↓ to Data High-Impedance (during a Read Data command)	0	—	80	ns	
TDLY	Data Input not Driven to Next Clock Input (delay required between command/data or command/command)	1.0	—	—	μs	
TERAB	Bulk Erase Cycle Time	—	—	25.2	ms	
TERAR	Row Erase Cycle Time	—	—	2.8	ms	
TPINT	Internally Timed Programming Operation Time	—	—	2.8	ms	Program memory
		—	—	5.6	ms	Configuration Words/ Data EEPROM Memory
TPEXT	Delay Required between Begin Externally Timed Programming and End Externally Timed Programming Commands	1.0	—	2.1	ms	Note 3
TDIS	Delay Required after End Externally Timed Programming Command	300	—	—	μs	
TEXIT	Time Delay when Exiting Program/Verify Mode	1	—	—	μs	

- Note 1:** Bulk Erased devices default to Brown-out Reset enabled with BORV = 1 (low trip point). VDDMIN is the VBOR threshold (with BORV = 1) when performing Low-Voltage Programming on a Bulk Erased device to ensure that the device is not held in Brown-out Reset.
- 2:** The hardware requires VDD to be above the BOR threshold, at the ~2.4V nominal setting, in order to perform Bulk Erase operations. This threshold does not depend on the BORV Configuration bit settings. The threshold is the same for both F and LF devices, even though the LF devices may not have a user-configurable ~2.4V nominal BOR trip point setting. Refer to the microcontroller device data sheet specifications for min./typ./max. limits of the VBOR level (at the BORV = 0 setting of F devices).
- 3:** Externally timed writes are not supported for Configuration and Calibration bits.

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APPENDIX A: REVISION HISTORY

Revision A (7/2017)

Initial release of the document.

APPENDIX B: PIC18(L)F25/26K83 DEVICE ID, CHECKSUMS AND PINOUT DESCRIPTIONS**TABLE B-1: CONFIGURATION WORD AND MASK**

Device	Device ID	Config 1L		Config 1H		Config 2L		Config 2H		Config 3L		Config 3H		Config 4L		Config 4H		Config 5L				
		Word	Mask	Word	Mask	Word	Mask	Word	Mask	Word	Mask	Word	Mask	Word	Mask	Word	Mask	Unprotected	Code-Protected	Mask	Word	Mask
PIC18F25K83	6EE0h	FF	77	FF	29	FF	FF	FF	BF	FF	7F	FF	3F	FF	9F	FF	2F	FF	FE	01	FF	00
PIC18F26K83	6EC0h	FF	77	FF	29	FF	FF	FF	BF	FF	7F	FF	3F	FF	9F	FF	2F	FF	FE	01	FF	00
PIC18LF25K83	6F20h	FF	77	FF	29	FF	FF	FF	BF	FF	7F	FF	3F	FF	9F	FF	2F	FF	FE	01	FF	00
PIC18LF26K83	6F00h	FF	77	FF	29	FF	FF	FF	BF	FF	7F	FF	3F	FF	9F	FF	2F	FF	FE	01	FF	00

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TABLE B-2: CHECKSUM VALUES

Device	Checksum			
	Unprotected		Code-Protected	
	Blank	00AAh at First and Last Address	Blank	00AAh at First and Last Address
PIC18F25K83	83ED	8343	0412	03FE
PIC18F26K83	03ED	0343	040A	03F6
PIC18LF25K83	83ED	8343	0412	03FE
PIC18LF26K83	03ED	0343	040A	03F6

**EXAMPLE B-1: CHECKSUM COMPUTED WITH PROGRAM CODE PROTECTION DISABLED:
PIC18(L)F25K83, BLANK DEVICE**

PIC18(L)F25K83	Sum of Memory addresses from 0000h to 7FFFh	8000h (8000h*00FFh)
	Configuration Word 1L	FFh
	Configuration Word 1L Mask	77h
	Configuration Word 1H	FFh
	Configuration Word 1H Mask	2Bh
	Configuration Word 2L	FFh
	Configuration Word 2L Mask	FFh
	Configuration Word 2H	FFh
	Configuration Word 2H Mask	BFh
	Configuration Word 3L	FFh
	Configuration Word 3L Mask	7Fh
	Configuration Word 3H	FFh
	Configuration Word 3H Mask	3Fh
	Configuration Word 4L	FFh
	Configuration Word 4L Mask	9Fh
	Configuration Word 4H	FFh
	Configuration Word 4H Mask	2Fh
	Configuration Word 5L Unprotected	FFh
	Configuration Word 5L Mask	01h
	Configuration Word 5H	FFh
	Configuration Word 5H Mask	00h

Checksum = 8000h + (FFh AND 77h) + (FFh AND 2Bh) + (FFh AND FFh) + (FFh AND BFh)
 + (FFh AND 7Fh) + (FFh AND 3Fh) + (FFh AND 9Fh) + (FFh AND 2Fh)
 + (FFh AND 01h) + (FFh AND 00h)
 = 8000h + 77h + 2Bh + FFh + BFh + 7Fh + 3Fh + 9Fh + 2Fh + 01h + 00h
 = 83EDh

PIC18(L)F25/26K83

EXAMPLE B-2: CHECKSUM COMPUTED WITH PROGRAM CODE PROTECTION DISABLED: PIC18(L)F25K83, 00AAh AT FIRST AND LAST ADDRESS

PIC18(L)F25K83	Sum of Memory Addresses from 0000h to 7FFFh	7F56h (AAh + (7FFEh * 00FFh) + AAh)
	Configuration Word 1L	FFh
	Configuration Word 1L Mask	77h
	Configuration Word 1H	FFh
	Configuration Word 1H Mask	2Bh
	Configuration Word 2L	FFh
	Configuration Word 2L Mask	E3h
	Configuration Word 2H	FFh
	Configuration Word 2H Mask	BFh
	Configuration Word 3L	FFh
	Configuration Word 3L Mask	7Fh
	Configuration Word 3H	FFh
	Configuration Word 3H Mask	3Fh
	Configuration Word 4L	FFh
	Configuration Word 4L Mask	9Fh
	Configuration Word 4H	FFh
	Configuration Word 4H Mask	2Fh
	Configuration Word 5L Unprotected	FFh
	Configuration Word 5L Mask	01h
	Configuration Word 5H	FFh
	Configuration Word 5H Mask	00h
	Checksum = 7F56h + (FFh AND 77h) + (FFh AND 2Bh) + (FFh AND FFh) + (FFh AND BFh) + (FFh AND 7Fh) + (FFh AND 3Fh) + (FFh AND 9Fh) + (FFh AND 2Fh) + (FFh AND 01h) + (FFh AND 00h) = 7F56h + 77h + 2Bh + FFh + BFh + 7Fh + 3Fh + 9Fh + 2Fh + 01h + 00h = C843h	

**EXAMPLE B-3: CHECKSUM COMPUTED WITH PROGRAM CODE PROTECTION ENABLED:
PIC18(L)F25K83, BLANK DEVICE**

PIC18(L)F25K83	Configuration Word 1L	FFh
	Configuration Word 1L Mask	77h
	Configuration Word 1H	FFh
	Configuration Word 1H Mask	2Bh
	Configuration Word 2L	FFh
	Configuration Word 2L Mask	FFh
	Configuration Word 2H	FFh
	Configuration Word 2H Mask	BFh
	Configuration Word 3L	FFh
	Configuration Word 3L Mask	7Fh
	Configuration Word 3H	FFh
	Configuration Word 3H Mask	3Fh
	Configuration Word 4L	FFh
	Configuration Word 4L Mask	9Fh
	Configuration Word 4H	FFh
	Configuration Word 4H Mask	2Fh
	Configuration Word 5L Protected	FEh
	Configuration Word 5L Mask	01h
	Configuration Word 5H	FFh
	Configuration Word 5H Mask	00h

$$\begin{aligned}
 \text{Checksum} &= (\text{FFh AND } 77\text{h}) + (\text{FFh AND } 2\text{Bh}) + (\text{FFh AND } \text{FFh}) + (\text{FFh AND } \text{BFh}) \\
 &\quad + (\text{FFh AND } 7\text{Fh}) + (\text{FFh AND } 3\text{Fh}) + (\text{FFh AND } 9\text{Fh}) + (\text{FFh AND } 2\text{Fh}) \\
 &\quad + (\text{FEh AND } 01\text{h}) + (\text{FFh AND } 00\text{h}) + \text{SUM_ID} \\
 &= 77\text{h} + 2\text{Bh} + \text{FFh} + \text{BFh} + 7\text{Fh} + 3\text{Fh} + 9\text{Fh} + 2\text{Fh} + 00\text{h} + 00\text{h} + 26\text{h} \\
 &= 0412\text{h}
 \end{aligned}$$

SUM_ID = Byte-wise sum of lower four bits of all User ID locations

$$\begin{aligned}
 \text{SUM_ID} &= 08\text{h} + 03\text{h} + 0\text{Eh} + 0\text{Bh} + 00\text{h} + 00\text{h} + 00\text{h} + 00\text{h} + 00\text{h} + 00\text{h} + 00\text{h} + 00\text{h} + 00\text{h} + 00\text{h} + 00\text{h} + 00\text{h} \\
 &= 26\text{h}
 \end{aligned}$$

PIC18(L)F25/26K83

EXAMPLE B-4: CHECKSUM COMPUTED WITH PROGRAM CODE PROTECTION ENABLED: PIC18(L)F25K83, 00AAh AT FIRST AND LAST ADDRESS

PIC18(L)F25K83	Configuration Word 1L	FFh
	Configuration Word 1L Mask	77h
	Configuration Word 1H	FFh
	Configuration Word 1H Mask	2Bh
	Configuration Word 2L	FFh
	Configuration Word 2L Mask	FFh
	Configuration Word 2H	FFh
	Configuration Word 2H Mask	BFh
	Configuration Word 3L	FFh
	Configuration Word 3L Mask	7Fh
	Configuration Word 3H	FFh
	Configuration Word 3H Mask	3Fh
	Configuration Word 4L	FFh
	Configuration Word 4L Mask	9Fh
	Configuration Word 4H	FFh
	Configuration Word 4H Mask	2Fh
	Configuration Word 5L Protected	FEh
	Configuration Word 5L Mask	01h
	Configuration Word 5H	FFh
	Configuration Word 5H Mask	00h
Checksum = (FFh AND 77h) + (FFh AND 2Bh) + (FFh AND FFh) + (FFh AND BFh) + (FFh AND 7Fh) + (FFh AND 3Fh) + (FFh AND 9Fh) + (FFh AND 2Fh) + (FEh AND 01h) + (FFh AND 00h) + SUM_ID = 77h + 2Bh + FFh + BFh + 7Fh + 3Fh + 9Fh + 2Fh + 00h + 00h + 12h = 03FEh		
SUM_ID = Bitwise sum of lower four bits of all User ID locations		
SUM_ID = 08h + 03h + 04h + 01h + 00h + 00h + 00h + 00h + 00h + 00h + 00h + 00h + 00h + 00h + 00h + 00h = 12h		

PIC18(L)F25/26K83

TABLE B-3: PROGRAMMING PIN LOCATIONS BY PACKAGE TYPE

Device	Package	Package Code	Package Drawing Number ⁽¹⁾	VDD	VSS	MCLR		ICSPCLK		ICSPDAT	
				PIN	PIN	PIN	PORT	PIN	PORT	PIN	PORT
PIC18(L)F25K83 PIC18(L)F26K83	28-Pin SPDIP	(SP)	C04-070	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin SOIC	(SO)	C04-052	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin SSOP	(SS)	C04-073	20	19,8	1	RE3	27	RB6	28	RB7
	28-Pin QFN	(ML)	C04-105	17	16,5	26	RE3	24	RB6	25	RB7
	28-Pin UQFN	(MV)	C04-152	17	16,5	26	RE3	24	RB6	25	RB7

Note 1: The most current package drawings can be found in the Microchip Packaging Specification, DS00000049, found at <http://www.microchip.com/packaging>. The drawing numbers listed above do not include the current revision designator which is added at the end of the number.

TABLE B-4: SUMMARY OF CONFIGURATION WORDS

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Default/ Unprogrammed Value
30 0000h	CONFIG 1L	—	RSTOSC2	RSTOSC1	RSTOSC0	—	FEXTOSC2	FEXTOSC1	FEXTOSC0	1111 1111
30 0001h	CONFIG 1H	—	—	FCMEN	—	CSWEN	—	PR1WAY	CLKOUTEN	1111 1111
30 0002h	CONFIG 2L	BOREN1	BOREN0	LPBOREN	IVT1WAY	MVECEN	PWRTS1	PWRTS0	MCLRE	1111 1111
30 0003h	CONFIG 2H	XINST	—	DEBUG	STVREN	PPS1WAY	ZCDDIS	BORV1	BORV0	1111 1111
30 0004h	CONFIG 3L	—	WDTE1	WDTE0	WDTCP4S	WDTCP3S	WDTCP2S	WDTCP1S	WDTCP0S	1111 1111
30 0005h	CONFIG 3H	—	—	WDTCCS2	WDTCCS1	WDTCCS0	WDTCWS2	WDTCWS1	WDTCWS0	1111 1111
30 0006h	CONFIG 4L	WRTAPP	—	—	SAFEN	BBEN	BBSIZE2	BBSIZE1	BBSIZE0	1111 1111
30 0007h	CONFIG 4H	—	—	LVP	—	WRTSAF	WRTD	WRTC	WRTB	1111 1111
30 0008h	CONFIG 5L	—	—	—	—	—	—	—	CP	1111 1111
30 0009h	CONFIG 5H	—	—	—	—	—	—	—	—	1111 1111

REGISTER B-1: CONFIGURATION WORD 1L (30 0000h) – OSCILLATORS

U-1	R/W-1	R/W-1	R/W-1	U-1	R/W-1	R/W-1	R/W-1
—	RSTOSC2	RSTOSC1	RSTOSC0	—	FEXTOSC2	FEXTOSC1	FEXTOSC0
bit 7							bit 0

Legend:

R = Readable bit

W = Writable bit

U = Unimplemented bit, read as '1'

-n = Value for blank device

'1' = Bit is set

'0' = Bit is cleared

x = Bit is unknown

bit 7 **Unimplemented:** Read as '1'

bit 6-4 **RSTOSC<2:0>:** Power-up Default Value for COSC bits
 This value is the Reset default value for COSC and selects the oscillator first used by user software. Refer to COSC operation.
 111 = EXTOSC operating per FEXTOSC<2:0> bits (device manufacturing default)
 110 = HFINTOSC with HFFRQ = 4 MHz and CDIV = 4:1
 101 = LFINTOSC
 100 = SOSC
 011 = Reserved
 010 = EXTOSC with 4x PLL, with EXTOSC operating per FEXTOSC<2:0> bits
 001 = HFINTOSC with HFFRQ = 16 MHz and CDIV = 1:1 and the 4x PLL enabled
 000 = HFINTOSC with HFFRQ = 64 MHz and CDIV = 1:1; resets COSC/NOSC to 3'b110

bit 3 **Unimplemented:** Read as '1'

bit 2-0 **FEXTOSC<2:0>:** FEXTOSC External Oscillator Mode Selection bits
 111 = EC (External Clock) above 8 MHz; PFM set to high power (device manufacturing default)
 110 = EC (External Clock) for 500 kHz to 8 MHz; PFM set to medium power
 101 = EC (External Clock) below 500 kHz; PFM set to low power
 100 = Oscillator is not enabled
 011 = Reserved (do not use)
 010 = HS (crystal oscillator) above 8 MHz; PFM set to high power
 001 = XT (crystal oscillator) above 500 kHz, below 8 MHz; PFM set to medium power
 000 = LP (crystal oscillator) optimized for 32.768 kHz; PFM set to low power

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REGISTER B-2: CONFIGURATION WORD 1H (30 0001h) – OSCILLATORS

U-1	U-1	R/W-1	U-1	R/W-1	U-1	U-1	R/W-1
—	—	FCMEN	—	CSWEN	—	PR1WAY	CLKOUTEN
bit 7							bit 0

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '1'
 -n = Value for blank device '1' = Bit is set '0' = Bit is cleared x = Bit is unknown

- bit 7-6 **Unimplemented:** Read as '1'
- bit 5 **FCMEN:** Fail-Safe Clock Monitor Enable bit
 1 = FSCM timer is enabled
 0 = FSCM timer is disabled
- bit 4 **Unimplemented:** Read as '1'
- bit 3 **CSWEN:** Clock Switch Enable bit
 1 = Writing to NOSC and NDIV is allowed
 0 = The NOSC and NDIV bits cannot be changed by user software
- bit 2 **Unimplemented:** Read as '1'
- bit 1 **PR1WAY:** PRLOCKED bit One-way Set Enable bit
 1 = PRLOCKED bit can be cleared and set only once; PR registers remain locked after one clear/set cycle
 0 = PRLOCKED bit can be set and cleared repeatedly (subject to the unlock sequence)
- bit 0 **CLKOUTEN:** Clock Out Enable bit
 If FEXTOSC<2:0> = EC (high, mid or low) or Not Enabled:
 1 = CLKOUT function is disabled; I/O or oscillator function on OSC2
 0 = CLKOUT function is enabled; Fosc/4 clock appears at OSC2
 Otherwise:
 This bit is ignored.

REGISTER B-3: CONFIGURATION WORD 2L (30 0002h) – SUPERVISOR

R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
BOREN1	BOREN0	$\overline{\text{LPBOREN}}$	IVT1WAY	MVECEN	PWRTS1	PWRTS0	MCLRE
bit 7							bit 0

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '1'
 -n = Value for blank device '1' = Bit is set '0' = Bit is cleared x = Bit is unknown

- bit 7-6 **BOREN<1:0>**: Brown-out Reset Enable bits
 When enabled, Brown-out Reset Voltage (VBOR) is set by the BORV bit.
 11 = Brown-out Reset is enabled, SBOREN bit is ignored
 10 = Brown-out Reset is enabled while running, disabled in Sleep; SBOREN is ignored
 01 = Brown-out Reset is enabled according to SBOREN
 00 = Brown-out Reset is disabled
- bit 5 **LPBOREN**: Low-Power BOR Enable bit
 1 = Low-power BOR is disabled
 0 = Low-power BOR is enabled
- bit 4 **IVT1WAY**: IVTLOCK bit One-Way Set Enable bit
 1 = IVTLOCK bit can be cleared and set only once; IVT registers remain locked after one clear/set cycle
 0 = IVTLOCK bit can be set and cleared repeatedly (subject to the unlock sequence)
- bit 3 **MVECEN**: Multi-vector Enable bit
 1 = Multi-vector enabled; Vector table used for interrupts
 0 = Legacy interrupt behavior
- bit 2-1 **PWRTS<1:0>**: Power-up Timer Selection bits
 11 = PWRT is disabled
 10 = PWRT set at 64 ms
 01 = PWRT set at 16 ms
 00 = PWRT set at 1 ms
- bit 0 **MCLRE**: Master Clear ($\overline{\text{MCLR}}$) Enable bit
If LVP = 1:
 RE3 pin function is $\overline{\text{MCLR}}$.
If LVP = 0:
 1 = $\overline{\text{MCLR}}$ pin is $\overline{\text{MCLR}}$
 0 = $\overline{\text{MCLR}}$ pin function is a port defined function

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REGISTER B-4: CONFIGURATION WORD 2H (30 0003h) – SUPERVISOR

R/W-1	U-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
$\overline{\text{XINST}}$	—	$\overline{\text{DEBUG}}$	STVREN	PPS1WAY	ZCDDIS	BORV1 ⁽¹⁾	BORV0 ⁽¹⁾
bit 7							bit 0

Legend:

R = Readable bit

W = Writable bit

U = Unimplemented bit, read as '1'

-n = Value for blank device

'1' = Bit is set

'0' = Bit is cleared

x = Bit is unknown

- bit 7 **$\overline{\text{XINST}}$** : Extended Instruction Set Enable bit
 1 = Extended instruction set and Indexed Addressing mode are disabled (Legacy mode)
 0 = Extended instruction set and Indexed Addressing mode are enabled
- bit 6 **Unimplemented**: Read as '1'
- bit 5 **$\overline{\text{DEBUG}}$** : Debugger Enable bit
 1 = Background debugger is disabled
 0 = Background debugger is enabled
- bit 4 **STVREN**: Stack Overflow/Underflow Reset Enable bit
 1 = Stack overflow or underflow will cause a Reset
 0 = Stack overflow or underflow will not cause a Reset
- bit 3 **PPS1WAY**: PPSLOCK One-Way Set Enable bit
 1 = PPSLOCK bit can be cleared and set only once; PPS registers remain locked after one clear/set cycle
 0 = PPSLOCK bit can be set and cleared repeatedly (subject to the unlock sequence)
- bit 2 **ZCDDIS**: Zero-Cross Detect Disable bit
 1 = ZCD is disabled; ZCD can be enabled by setting the ZCDSEN bit of the ZCDCON register
 0 = ZCD is always enabled
- bit 1-0 **BORV<1:0>**: Brown-out Reset Voltage Selection bits⁽¹⁾
PIC18FXXK83 Devices:
 11 = Brown-out Reset Voltage (VBOR) is set to 2.45V
 10 = Brown-out Reset Voltage (VBOR) is set to 2.45V
 01 = Brown-out Reset Voltage (VBOR) is set to 2.7V
 00 = Brown-out Reset Voltage (VBOR) is set to 2.85V
PIC18LFXXK83 Device:
 11 = Brown-out Reset Voltage (VBOR) is set to 1.90V
 10 = Brown-out Reset Voltage (VBOR) is set to 2.45V
 01 = Brown-out Reset Voltage (VBOR) is set to 2.7V
 00 = Brown-out Reset Voltage (VBOR) is set to 2.85V

Note 1: The higher voltage setting is recommended for operation at or above 16 MHz.

PIC18(L)F25/26K83

REGISTER B-5: CONFIGURATION WORD 3L (30 0004h) – WINDOWED WATCHDOG TIMER

U-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
—	WDTE1	WDTE0	WDTCP54	WDTCP53	WDTCP52	WDTCP51	WDTCP50
bit 7							bit 0

Legend:

R = Readable bit

W = Writable bit

U = Unimplemented bit, read as '1'

-n = Value for blank device

'1' = Bit is set

'0' = Bit is cleared

x = Bit is unknown

bit 7

Unimplemented: Read as '1'

bit 6-5

WDTE<1:0>: WDT Operating Mode bits

00 = WDT is disabled, SWDTEN is ignored

01 = WDT is enabled/disabled by the SWDTEN bit in WDTCON0

10 = WDT is enabled while Sleep = 0, suspended when Sleep = 1; SWDTEN is ignored

11 = WDT is enabled regardless of Sleep; SWDTEN is ignored

bit 4-0

WDTCP5<4:0>: WDT Period Select bits

WDTCP5<4:0>	WDTPS at POR				Software Control of WDTPS?
	Value	Divider Ratio		Typical Time-out (F _{IN} = 31 kHz)	
00000	00000	1:32	2 ⁵	1 ms	No
00001	00001	1:64	2 ⁶	2 ms	
00010	00010	1:128	2 ⁷	4 ms	
00011	00011	1:256	2 ⁸	8 ms	
00100	00100	1:512	2 ⁹	16 ms	
00101	00101	1:1024	2 ¹⁰	32 ms	
00110	00110	1:2048	2 ¹¹	64 ms	
00111	00111	1:4096	2 ¹²	128 ms	
01000	01000	1:8192	2 ¹³	256 ms	
01001	01001	1:16384	2 ¹⁴	512 ms	
01010	01010	1:32768	2 ¹⁵	1s	
01011	01011	1:65536	2 ¹⁶	2s	
01100	01100	1:131072	2 ¹⁷	4s	
01101	01101	1:262144	2 ¹⁸	8s	
01110	01110	1:524299	2 ¹⁹	16s	
01111	01111	1:1048576	2 ²⁰	32s	
10000	10000	1:2097152	2 ²¹	64s	
10001	10001	1:4194304	2 ²²	128s	
10010	10010	1:8388608	2 ²³	256s	
10011	10011	1:32	2 ⁵	1 ms	No
...	...				
11110	11110	1:65536	2 ¹⁶	2s	Yes
11111	01011				

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REGISTER B-6: CONFIGURATION WORD 3H (30 0005h) – WINDOWED WATCHDOG TIMER

U-1	U-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
—	—	WDTCCS2	WDTCCS1	WDTCCS0	WDTCWS2	WDTCWS1	WDTCWS0
bit 7							bit 0

Legend:

R = Readable bit

W = Writable bit

U = Unimplemented bit, read as '1'

-n = Value for blank device

'1' = Bit is set

'0' = Bit is cleared

x = Bit is unknown

bit 7-6 **Unimplemented:** Read as '1'

bit 5-3 **WDTCCS<2:0>:** WDT Input Clock Selector bits

If WDTE<1:0> Fuses = 2'b00:

This bit is ignored.

Otherwise:

000 = WDT reference clock is the 31.0 kHz LFINTOSC (default value)

001 = WDT reference clock is the 31.25 kHz HFINTOSC (MFINTOSC)

010 = WDT reference clock is SOSC

011 = Reserved (default to LFINTOSC)

•

•

110 = Reserved (default to LFINTOSC)

111 = Software control

bit 2-0 **WDTCWS<2:0>:** WDT Window Select bits

WDTCWS	Window at POR			Software Control of Window	Keyed Access Required?
	Value	Window Delay Percent of Time	Window Opening Percent of Time		
000	000	87.5	12.5	No	Yes
001	001	75	25		
010	010	62.5	37.5		
011	011	50	50		
100	100	37.5	62.5		
101	101	25	75		
110	111	n/a	100		
111	111	n/a	100	Yes	No

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REGISTER B-7: CONFIGURATION WORD 4L (30 0006h) – MEMORY WRITE PROTECTION

R/W-1	U-1	U-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
WRTAPP ⁽¹⁾	—	—	SAFEN ⁽¹⁾	BBEN ⁽¹⁾	BBSIZE2 ⁽²⁾	BBSIZE1 ⁽²⁾	BBSIZE0 ⁽²⁾
bit 7							bit 0

Legend:

R = Readable bit

W = Writable bit

U = Unimplemented bit, read as '1'

-n = Value for blank device

'1' = Bit is set

'0' = Bit is cleared

x = Bit is unknown

bit 7 **WRTAPP:** Application Block Write Protection bit

1 = Application Block NOT write-protected

0 = Application Block write-protected

bit 6-5 **Unimplemented:** Read as '1'

bit 4 **SAFEN:** Storage Area Flash Enable bit

1 = SAF disabled

0 = SAF enabled

bit 3 **BBEN:** Boot Block Enable bit

1 = Boot Block disabled

0 = Boot Block enabled

bit 2-0 **BBSIZE<2:0>:** Boot Block Size Selection bits

Refer to [Table B-5](#).

Note 1: Bits are implemented as sticky bits. Once protection is enabled through ICSP or a self write, it can only be reset through a bulk erase.

2: BBSIZ bits can only be changed when $\overline{\text{BBEN}} = 1$. Once $\overline{\text{BBEN}} = 0$, BBSIZ can only be changed through a bulk erase.

TABLE B-5: BOOT BLOCK SIZE BITS

$\overline{\text{BBEN}}$	BBSIZE[2:0]	Boot Block Size (words)	END_ADDRESS_BOOT	Device Size ⁽¹⁾	
				16k	32k
1	xxx	0	—	X	X
0	111	512	00 03FFh	X	X
0	110	1024	00 07FFh	X	X
0	101	2048	00 0FFFh	X	X
0	100	4096	00 1FFFh	X	X
0	011	8192	00 3FFFh	X	X
0	010	16384	00 7FFFh	—	X
0	001	32768	00 FFFFh	Note 2	
0	000	32768	00 FFFFh		

Note 1: For each device, the quoted device size specification is listed in [Table 2-1](#).

2: The maximum boot block size is half the user program memory size. All selections higher than the maximum size default to maximum boot block size of half PFM. For example, all settings of BBSIZE = 000 through BBSIZE = 100, default to a boot block size of 4 kW on a 8 kW device.

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TABLE B-6: MEMORY MAP PARTITIONS AND PROTECTION

Region	Address	Partition			
		$\overline{\text{BBEN}} = 1$ $\overline{\text{SAFEN}} = 1$	$\overline{\text{BBEN}} = 1$ $\overline{\text{SAFEN}} = 0$	$\overline{\text{BBEN}} = 0$ $\overline{\text{SAFEN}} = 1$	$\overline{\text{BBEN}} = 0$ $\overline{\text{SAFEN}} = 0$
Program Flash Memory	00 0000h • • • END_ADDRESS_BOOT	APP CP, WRTAPP	APP CP, WRTAPP	BOOT CP, WRTB	BOOT CP, WRTB
	END_ADDRESS_BOOT + 1 • • • END_ADDRESS - 100h			APP CP, WRTAPP	APP CP, WRTAPP
	END_ADDRESS - FEh • • • END_ADDRESS		SAF CP, WRTSAF		SAF CP, WRTSAF
Configuration Words	30 0000h 30 0009h	CONFIG WRTC			
Data EEPROM	31 0000h 31 00FFh	Data EEPROM CP, WRTD			

- Note 1:** END_ADDRESS_BOOT is based on BOOTSIZ[2:0], see [Table B-5](#).
Note 2: END_ADDRESS is based on quoted flash size, see [Table 2-1](#).
Note 3: Refer to [Register B-7](#): Configuration Word 4L for BBEN and SAFEN definitions.

REGISTER B-8: CONFIGURATION WORD 4H (30 0007h) – MEMORY WRITE PROTECTION

U-1	U-1	R/W-1	U-1	R/W-1	R/W-1	R/W-1	R/W-1
—	—	LVP	—	WRTSAF (1)	WRTD (1)	WRTC (1)	WRTB (1)
bit 7							bit 0

Legend:

R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '1'
-n = Value for blank device	'1' = Bit is set	'0' = Bit is cleared
		x = Bit is unknown

bit 7-6 **Unimplemented:** Read as '1'

bit 5 **LVP:** Low-Voltage Programming Enable bit

1 = Low-voltage programming enabled. MCLR/VPP pin function is MCLR. MCLRE ([Register B-3](#)) is ignored.

0 = HV on MCLR/VPP must be used for programming.

Note: The LVP bit cannot be written (to zero) while operating from the LVP programming interface. The purpose of this rule is to prevent the user from dropping out of LVP mode while programming from LVP mode, or accidentally eliminating LVP mode from the configuration state

bit 4 **Unimplemented:** Read as '1'

bit 3 **WRTSAF:** Storage Area Flash (SAF) Write Protection bit

1 = SAF NOT write-protected

0 = SAF write-protected

Note: Unimplemented if SAF is not present and only applicable if $\overline{\text{SAFEN}} = 0$

bit 2 **WRTD:** Data EEPROM Write Protection bit

1 = Data EEPROM NOT write-protected

0 = Data EEPROM write-protected

Note: Unimplemented if data EEPROM is not present

bit 1 **WRTC:** Configuration Register Write Protection bit

1 = Configuration Register NOT write-protected

0 = Configuration Register write-protected

bit 0 **WRTB:** Boot Block Write Protection bit

1 = Boot Block NOT write-protected

0 = Boot Block write-protected

Note: Only applicable if $\overline{\text{BBEN}} = 0$

Note 1: Bits are implemented as sticky bits. Once protection is enabled through ICSP or a self write, it can only be reset through a bulk erase.

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REGISTER B-9: CONFIGURATION WORD 5L (30 0008h) – CODE PROTECTION

U-1	U-1	U-1	U-1	U-1	U-1	U-1	R/W-1
—	—	—	—	—	—	—	$\overline{\text{CP}}$
bit 7							bit 0

Legend:

R = Readable bit

W = Writable bit

U = Unimplemented bit, read as '1'

-n = Value for blank device

'1' = Bit is set

'0' = Bit is cleared

x = Bit is unknown

bit 7-1

Unimplemented: Read as '1'

bit 0

$\overline{\text{CP}}$: User Program Flash Memory and Data EEPROM Code Protection bit

1 = User Program Flash Memory and Data EEPROM code protection is disabled

0 = User Program Flash Memory and Data EEPROM code protection is enabled

APPENDIX C: DEVICE CONFIGURATION INFORMATION

TABLE C-1: DEVICE CONFIGURATION INFORMATION FOR PIC18(L)F25/26K83 DEVICES

ADDRESS	DESCRIPTION	VALUE	UNITS
3F FF00h - 3F FF01h	Erase Row Size	64	words
3F FF02h - 3F FF03h	Number of write latches per row	128	bytes
3F FF04h - 3F FF05h	Number of User Rows	See Table C-2	rows
3F FF06h - 3F FF07h	Data EEPROM memory size	1024	bytes
3F FF08h - 3F FF09h	Pin Count	28	pins

Note 1: These locations are read-only.

2: Erase size is the minimum erasable unit in the PFM, expressed as rows. The total device Flash memory capacity is (Row Size*Number of rows).

TABLE C-2: NUMBER OF USER ROWS

Part	Memory Size	Number of User Rows
PIC18(L)F25K83	16K	512
PIC18(L)F26K83	32K	1024

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 Fax: 91-80-3090-4123

India - New Delhi
 Tel: 91-11-4160-8631
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India - Pune
 Tel: 91-20-3019-1500

Japan - Osaka
 Tel: 81-6-6152-7160
 Fax: 81-6-6152-9310

Japan - Tokyo
 Tel: 81-3-6880-3770
 Fax: 81-3-6880-3771

Korea - Daegu
 Tel: 82-53-744-4301
 Fax: 82-53-744-4302

Korea - Seoul
 Tel: 82-2-554-7200
 Fax: 82-2-558-5932 or
 82-2-558-5934

Malaysia - Kuala Lumpur
 Tel: 60-3-6201-9857
 Fax: 60-3-6201-9859

Malaysia - Penang
 Tel: 60-4-227-8870
 Fax: 60-4-227-4068

Philippines - Manila
 Tel: 63-2-634-9065
 Fax: 63-2-634-9069

Singapore
 Tel: 65-6334-8870
 Fax: 65-6334-8850

Taiwan - Hsin Chu
 Tel: 886-3-5778-366
 Fax: 886-3-5770-955

Taiwan - Kaohsiung
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Taiwan - Taipei
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Thailand - Bangkok
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EUROPE

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Germany - Garching
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Germany - Haan
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Germany - Heilbronn
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Germany - Rosenheim
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Israel - Ra'anana
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Netherlands - Drunen
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Norway - Trondheim
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Poland - Warsaw
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Romania - Bucharest
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Spain - Madrid
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Sweden - Stockholm
 Tel: 46-8-5090-4654

UK - Wokingham
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